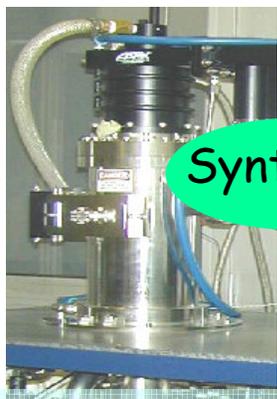


# Diamond Detector Applications at CEA-Saclay



# Le diamant à Saclay: de la synthèse aux dispositifs



Synthèse



dépôt chimique par plasma

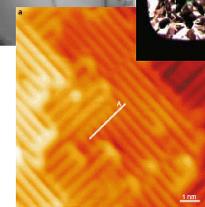


Substrats

Analyse optique, électrique, sous ray<sup>t</sup>, traitements plasma, Contacts, litho, défauts



Défauts, monoX, dopage



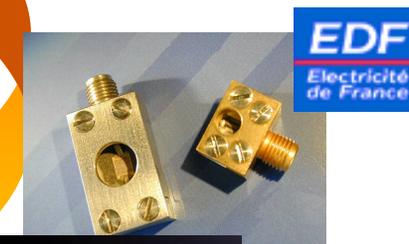
Etudes matériau bâtis UHV + caract.

PECVD microonde:  
Non-dopé : 3 bâtis, Ø5cm  
Dopage : 2 bâtis - 2003

Nouveaux marchés

Développement de dispositifs pour applications spécifiques

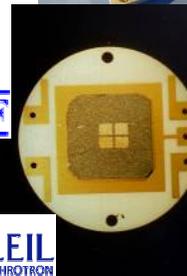
Capteurs



industrie (semiconducteur grand gap)

Bio-capteurs (biocompatibilité)

santé/dosimétrie (Z=6 : équivalence tissus)



détecteurs de rayonnements (inertes chimiquement, compatibles milieux hostiles)

# Diamond device fabrication at CEA

- ◆ Growth (3 reactors)
- ◆ Laser cut
- ◆ Device processing
- ◆ Defect 'passivating'
- ◆ Contacts
- ◆ Packaging



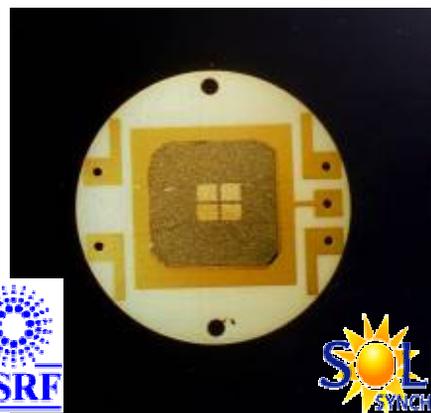
Growth



Films



Fast pulse metrology  
(Defence)



Beam monitors (ESRF)

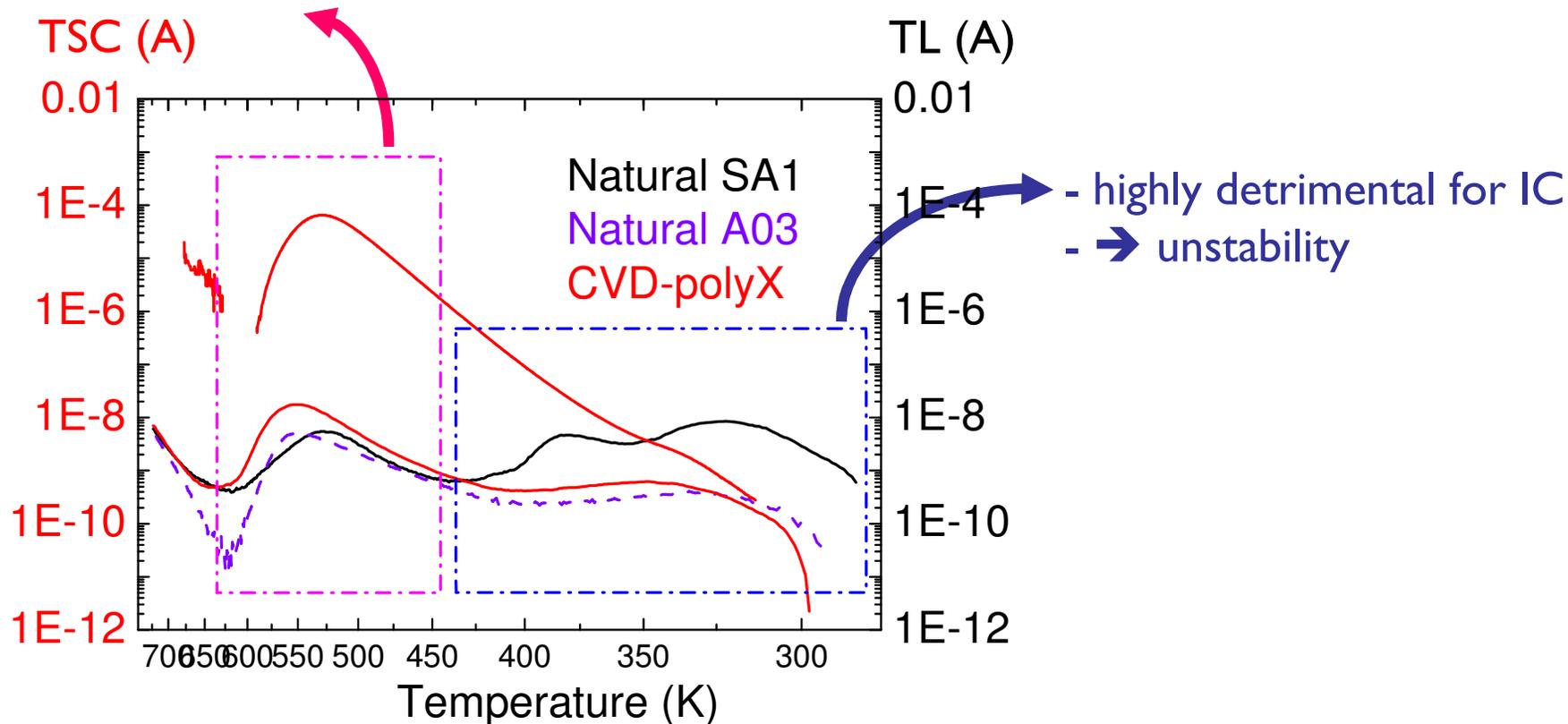


Corrosion hard alpha detectors  
(COGEMA)



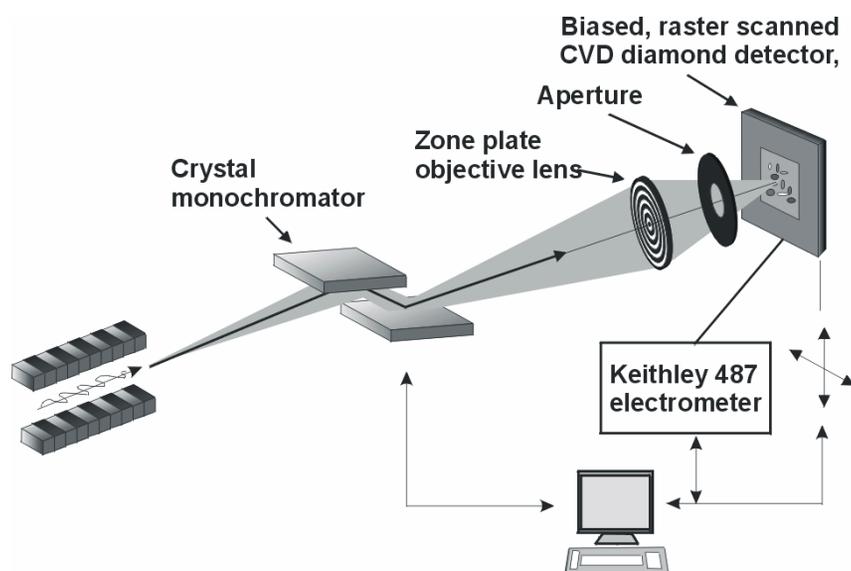
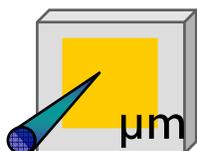
☞ CVD materials, as well as high quality IIa type diamonds inherently exhibit defect levels

- of interest for TL dosimetry
- stable at RT

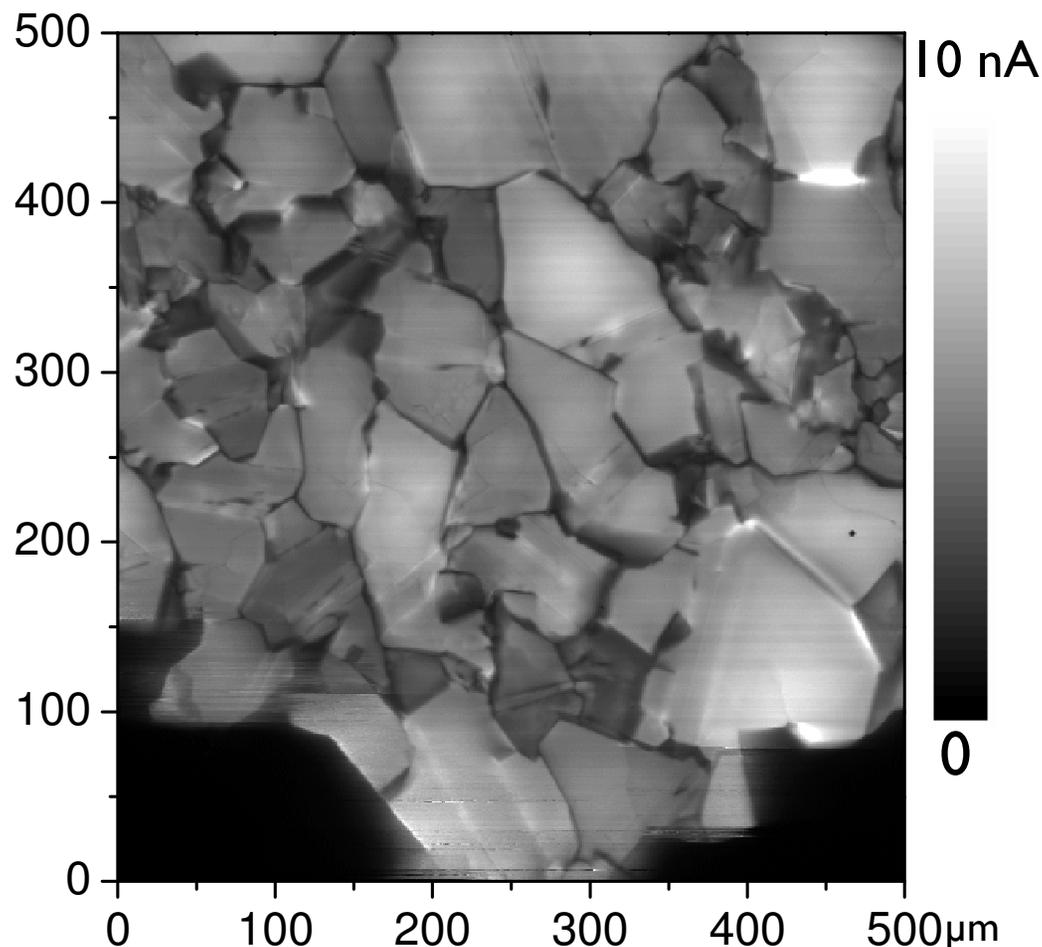


# Non-uniformity of the sensitivity

X-ray microbeam :  
 5 keV (Volume)  
 att. length : 150  $\mu\text{m}$  (1/e)  
 $\approx 1.4 \cdot 10^9$  ph/s  
 beam spot < 1  $\mu\text{m}$   
 resolution : 1  $\mu\text{m}$

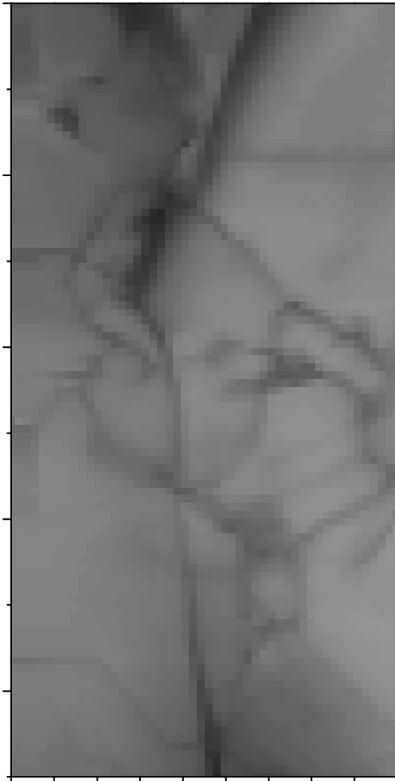


→ Comm. Avail. 300 $\mu\text{m}$  Det. Grade

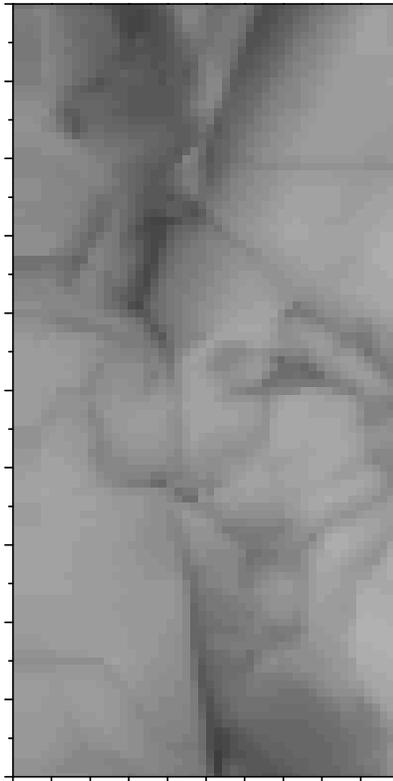


**Strong Non-uniformities observed**  
**→ Detrimental for beam metrology**

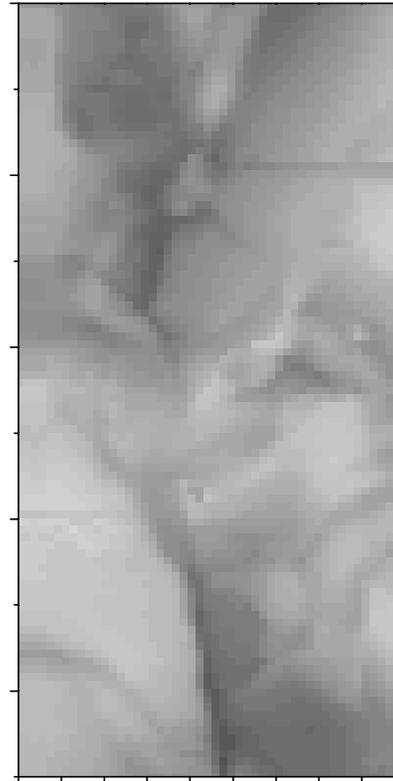
100 V  
3.3 kV/cm



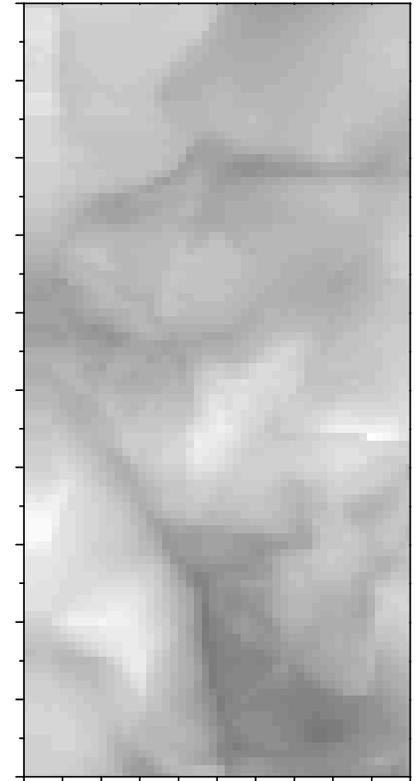
200 V  
6.6 kV/cm



400 V  
13.3 kV/cm



800 V  
26.6 kV/cm

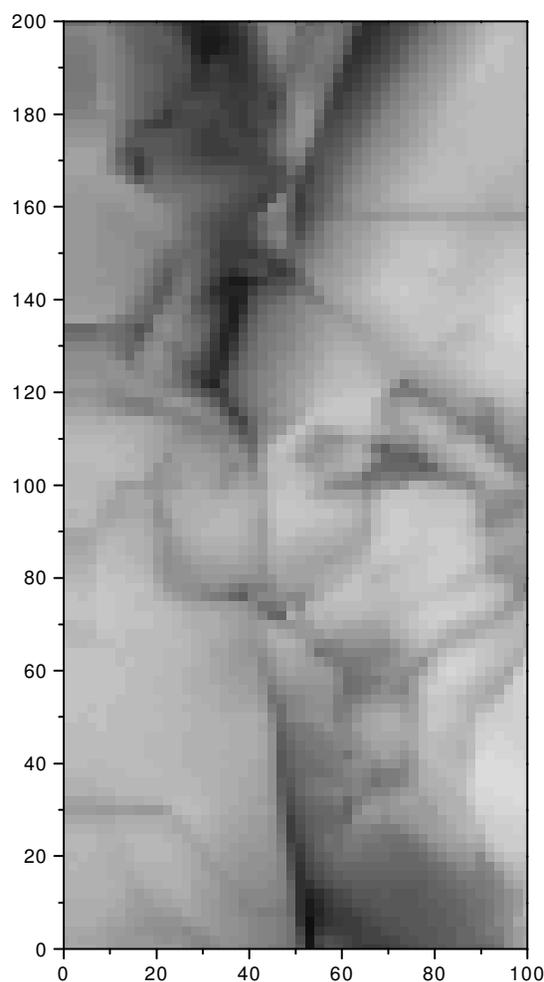


(Identical grey scale : 1 to 28 nA – log)

→ Velocity of saturation can be reached locally (likely from 10 kV/cm)

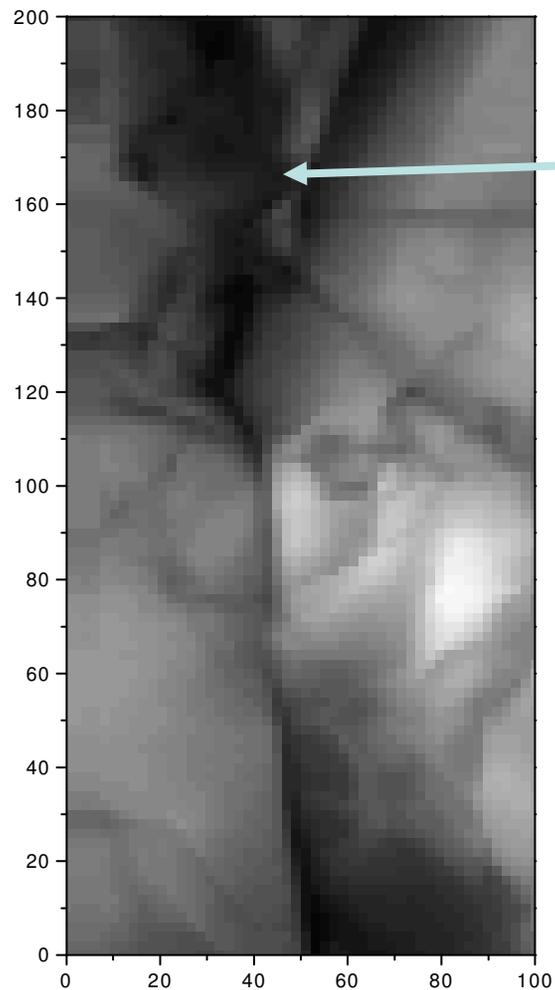
# Evidence of charge build-up

At 200V



At 200V, after one scan at 800V

13 nA

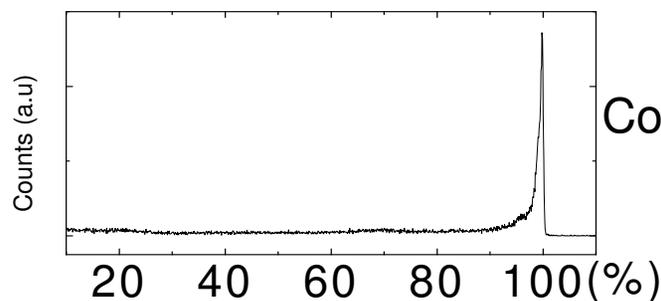


Darker area :  
Sensitivity is lower

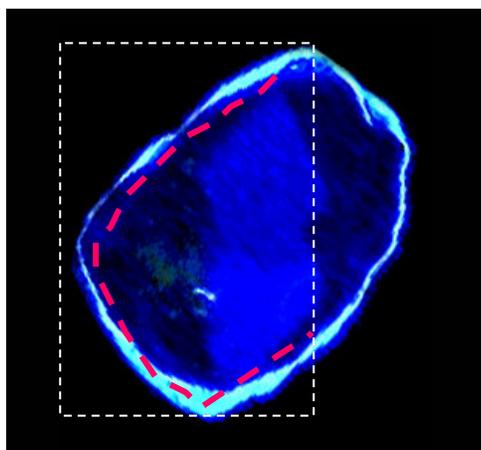
# Defects in natural SC diamonds

Similar measurement performed on high quality detector grade IIa type

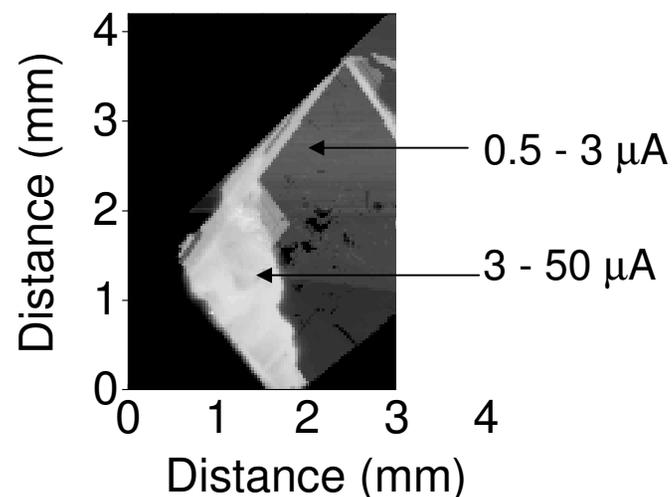
under  $^{241}\text{Am}$  alpha particles :  
**100% cool. efficiency,**  
**ideal response**



**Luminescence response**



**X-ray sensitivity : micro beam analysis**

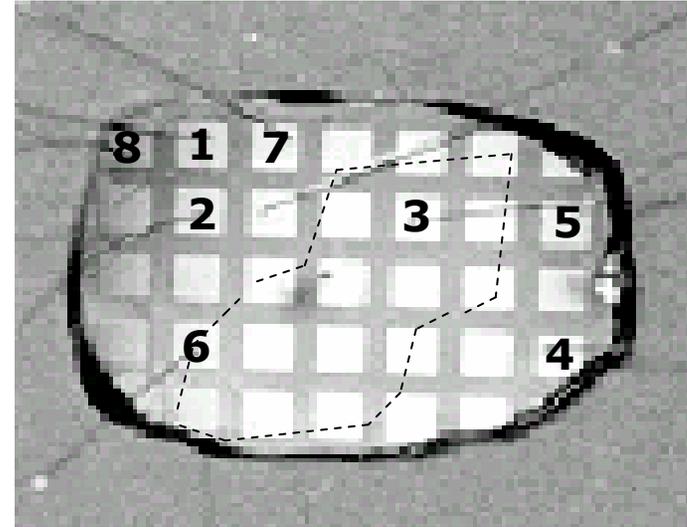
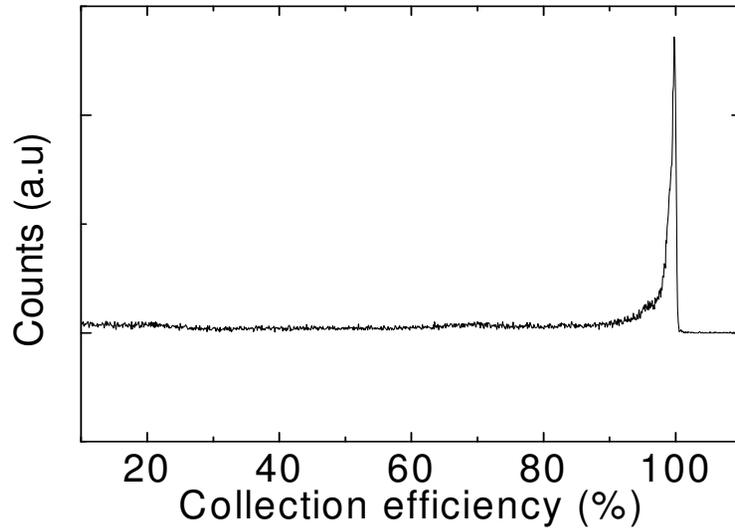


Defects here mostly associated with N



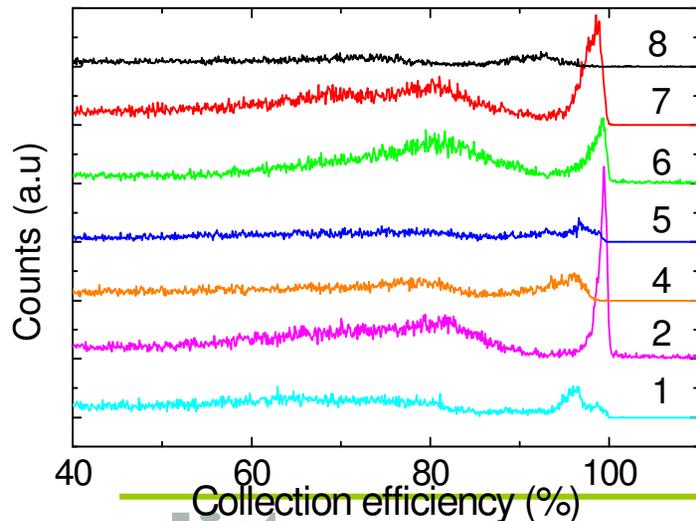
# High quality natural diamond detectors

## Alpha detection spectra



**BUT**

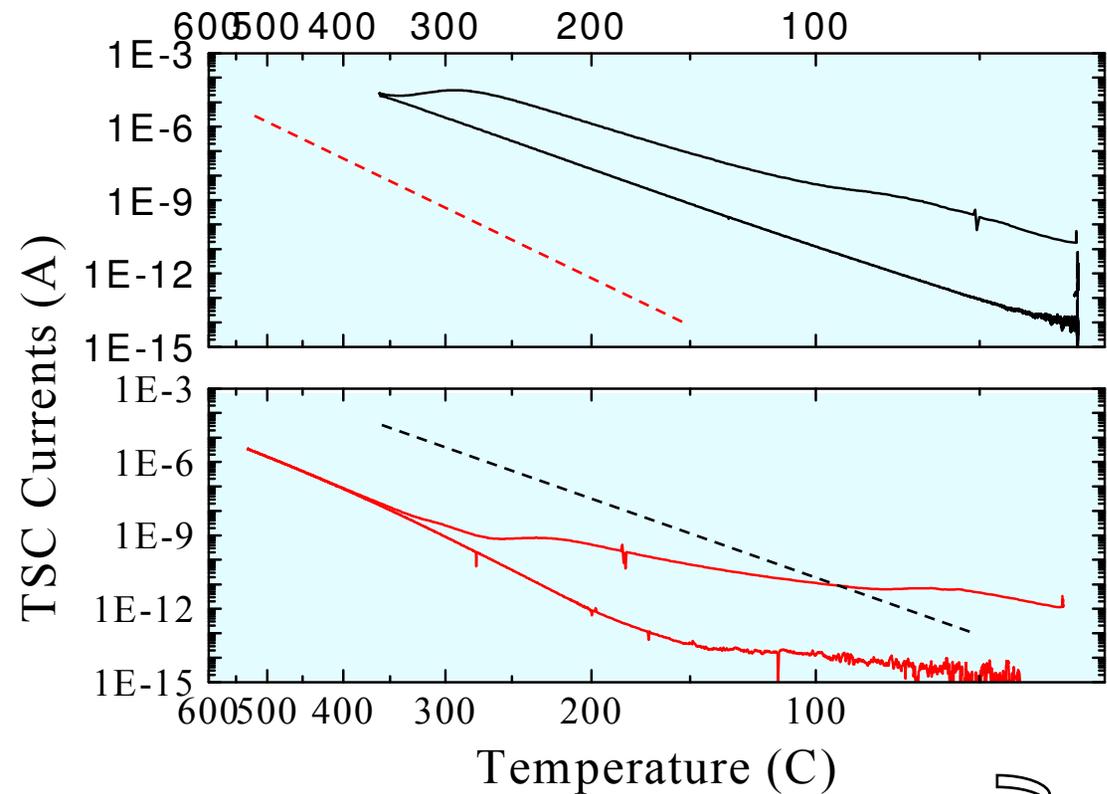
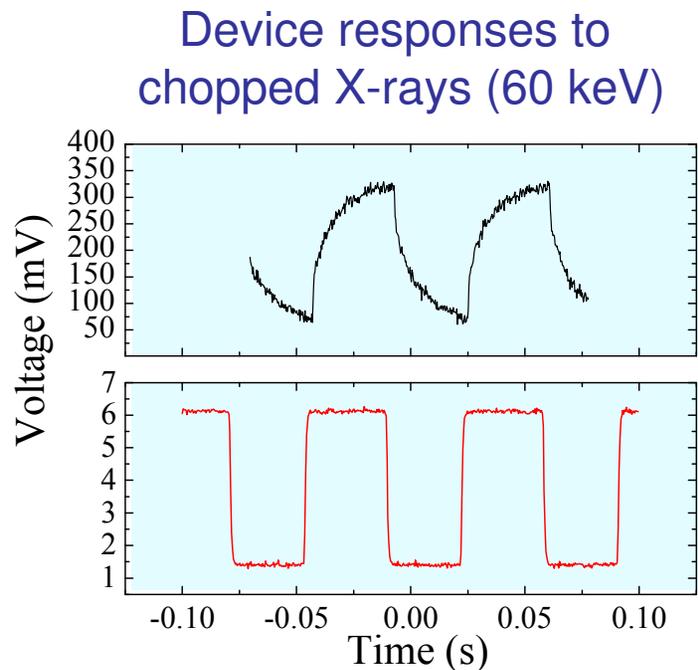
- global detection : collection efficiency reaches 100 %
- localised variation of the detection properties : blind zones vs high collection efficiency zones



list

## Impurities : effect on the response time

### TSC Signatures ( $10^4\text{V/cm}$ )



# Observed non-uniformity of the sensitivity

X-ray microbeam :

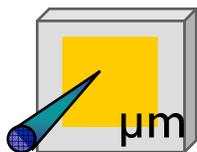
6 keV (Volume)

att. length : 150  $\mu\text{m}$  (1/e)

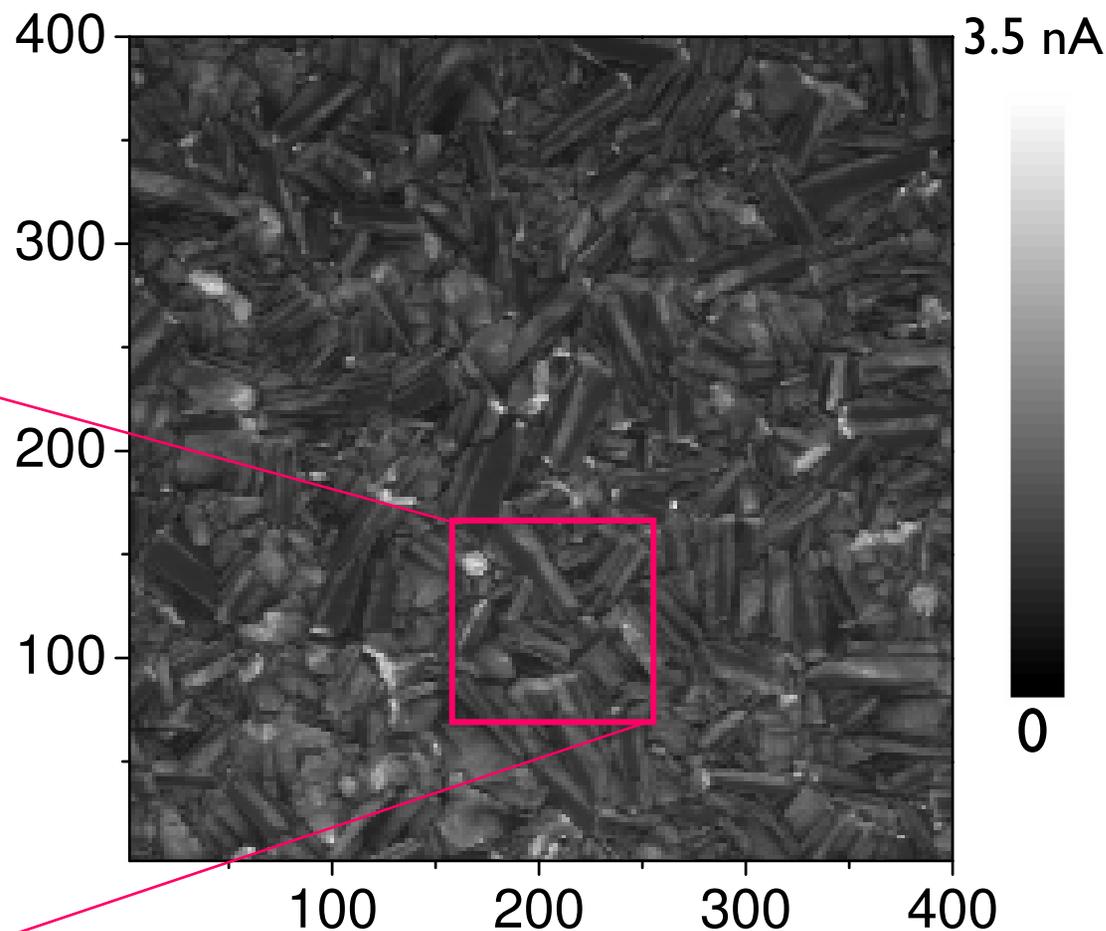
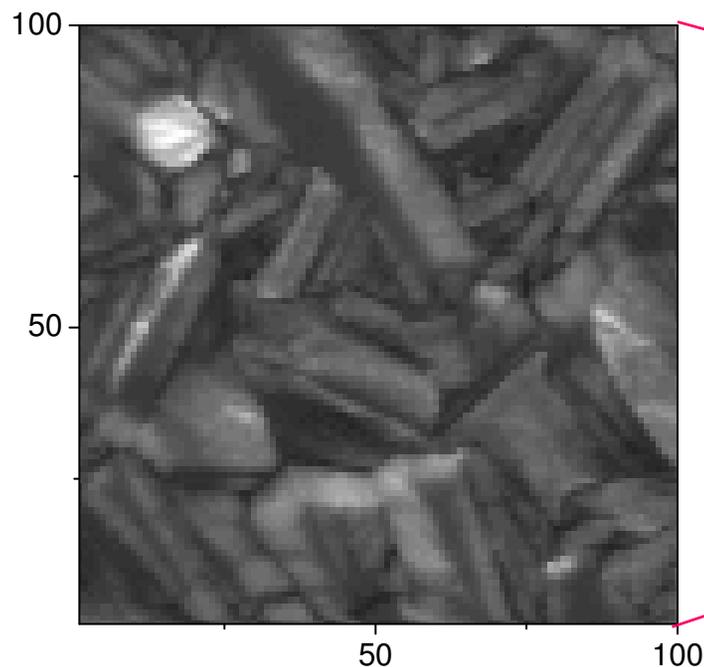
$\approx 5 \cdot 10^8$  ph/s

beam spot < 1  $\mu\text{m}$

resolution : 1  $\mu\text{m}$



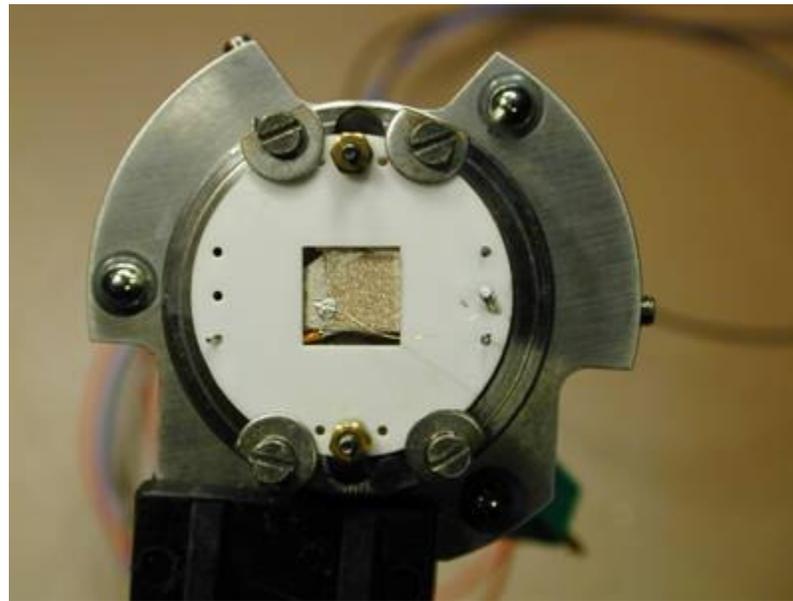
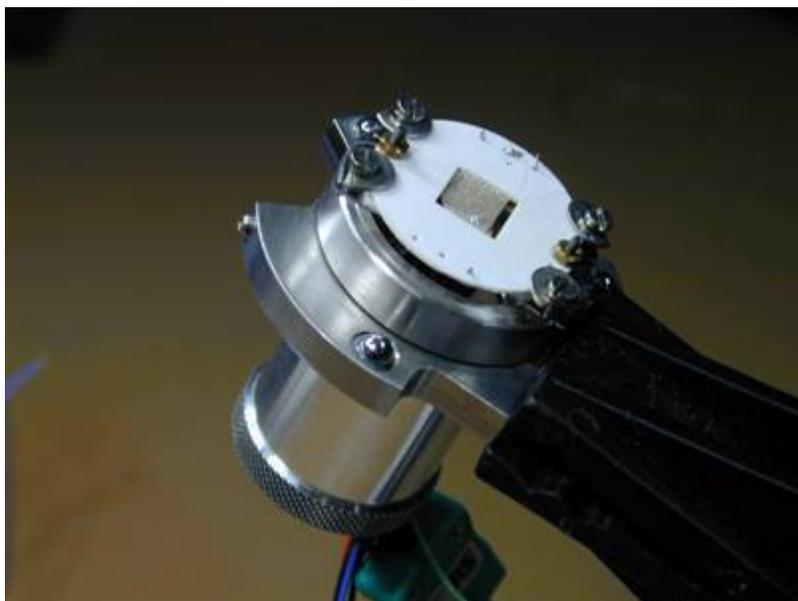
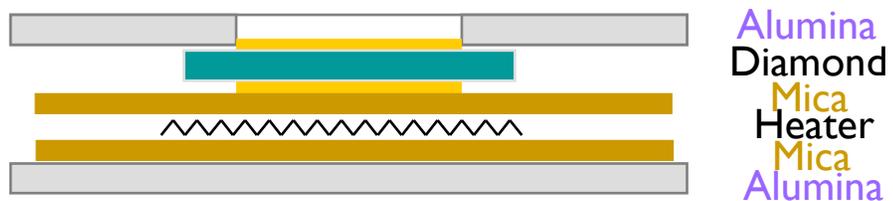
→ 150  $\mu\text{m}$  thick + smaller grains (CEA)



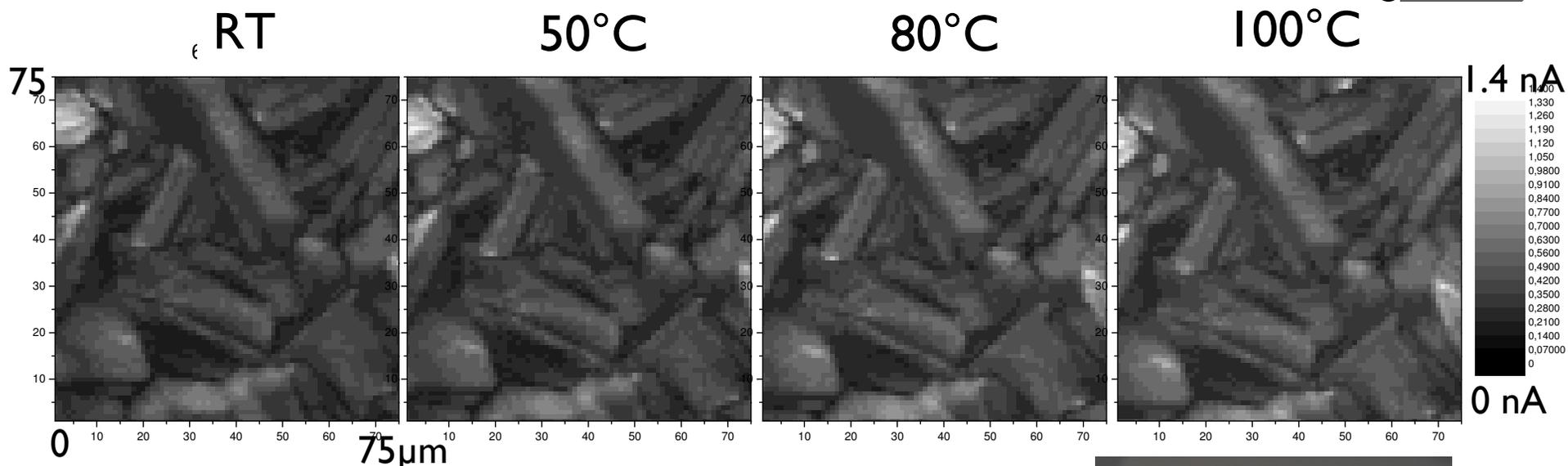
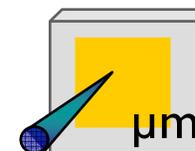
**Image may appear more uniform**  
**→ But what about charging-up effects ?**

# Temperature effects on the sensitivity maps

Sample mount equipped with resistive heater



# Effect of the temperature



Bias is 0.4 V/μm  
 5 10<sup>8</sup> photons/s, @ 6keV

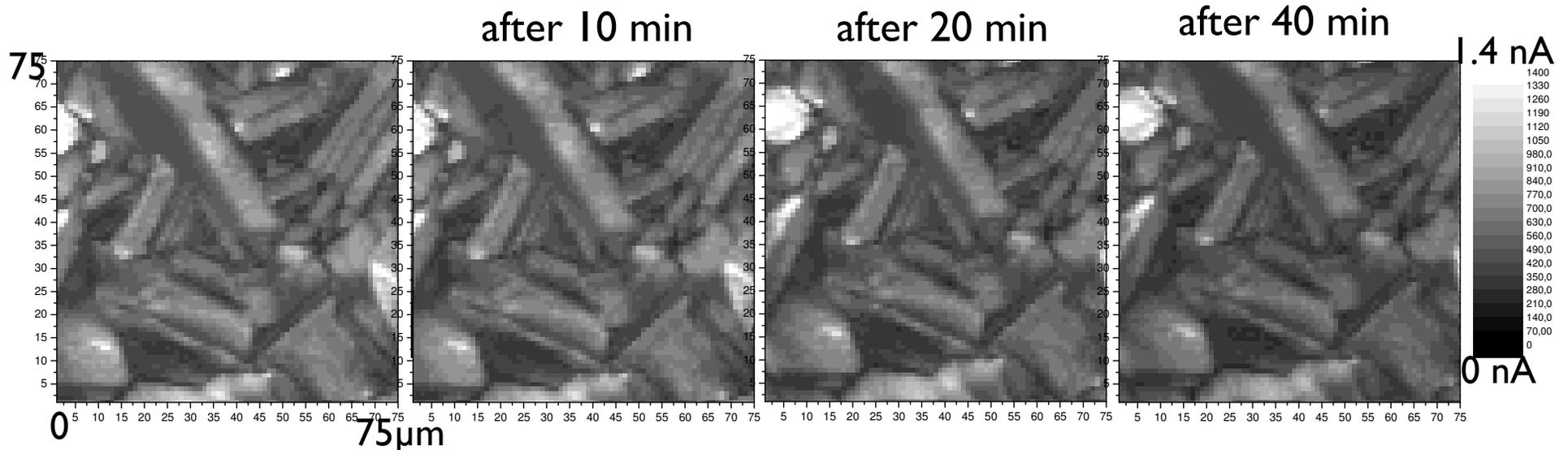
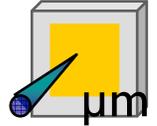
sample on  
 heating stage



➔ Hardly any influence of the temperature is observed

# Effect of the thermal detrapping

After each scan, the sample is kept under heat before measurement



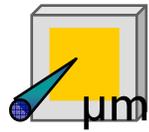
Temperature is kept at 100°C

Bias is 0.4 V/ $\mu\text{m}$

5  $10^8$  photons/s, @ 6keV

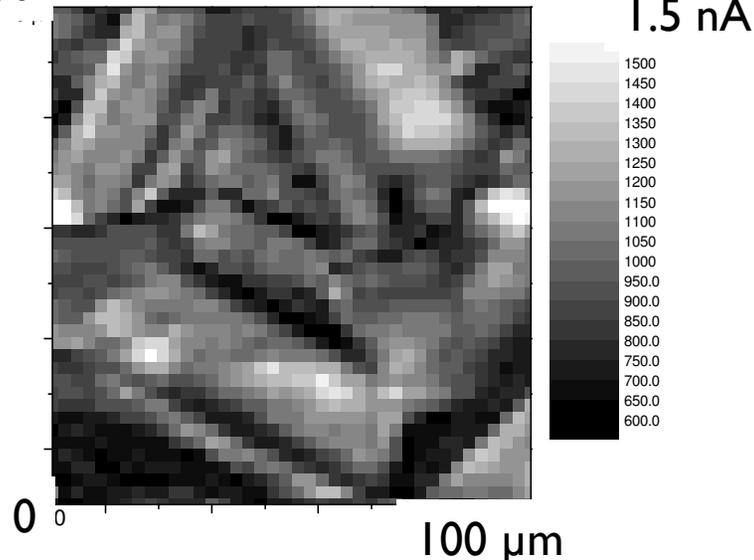
- Hardly any effect observed
- Thermal detrapping not significant ? Or immediate « re-pumping ? »

## Effect of high temperature annealings (300°C)

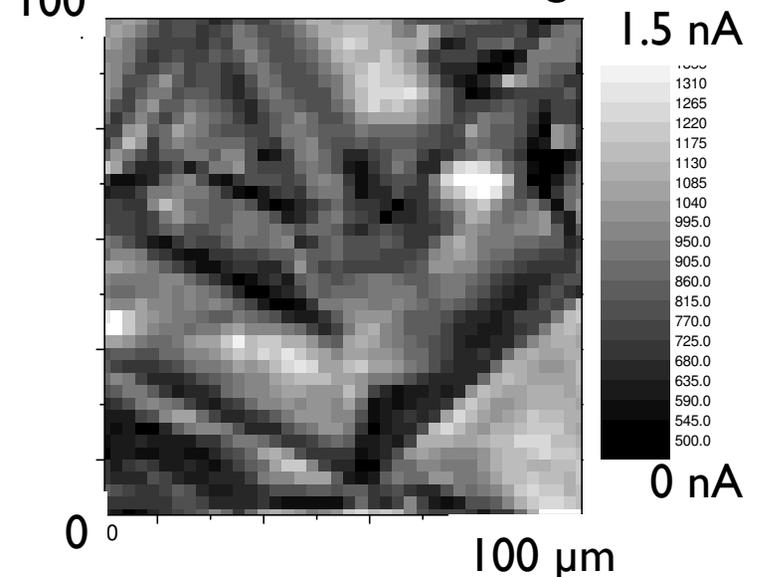


Bias is 1 V/ $\mu\text{m}$   
5  $10^8$  photons/s, @ 6keV

100 Before annealing



100 after 300°C annealing



Hardly any effect of the temperature is visible :

In fact, dose calculations  $\Rightarrow$  typ.  $10^5$  Gy/s at the focal point

$\rightarrow$  Pumping is instantaneous during measurement...

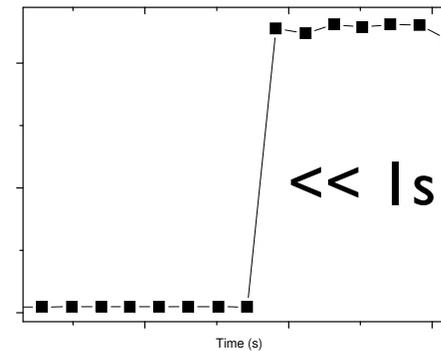
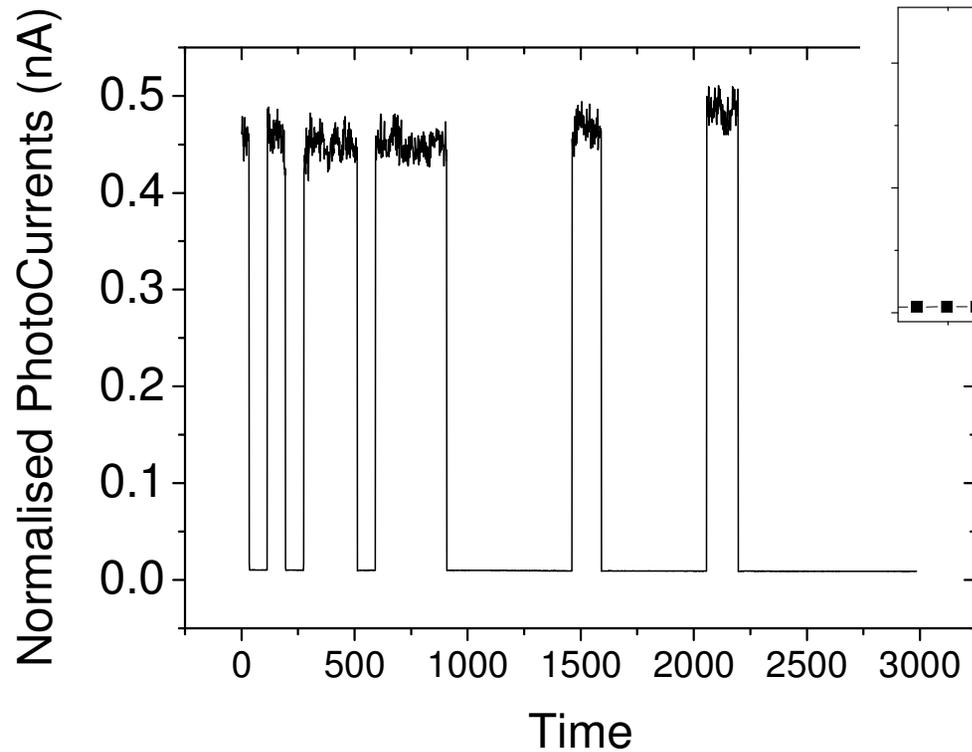
whatever the temperature...

$\rightarrow$  Trapping / Detrapping : not a real problem for synchrotron applications ?

# Dynamics of the photoresponse

Back to RT,

The response is probed dynamically (Beam On/Off) under  $\mu$ -beam



Hardly no pumping  
nor trapping/  
detrapping effects  
observed

# Specific detectors for very hostile environments

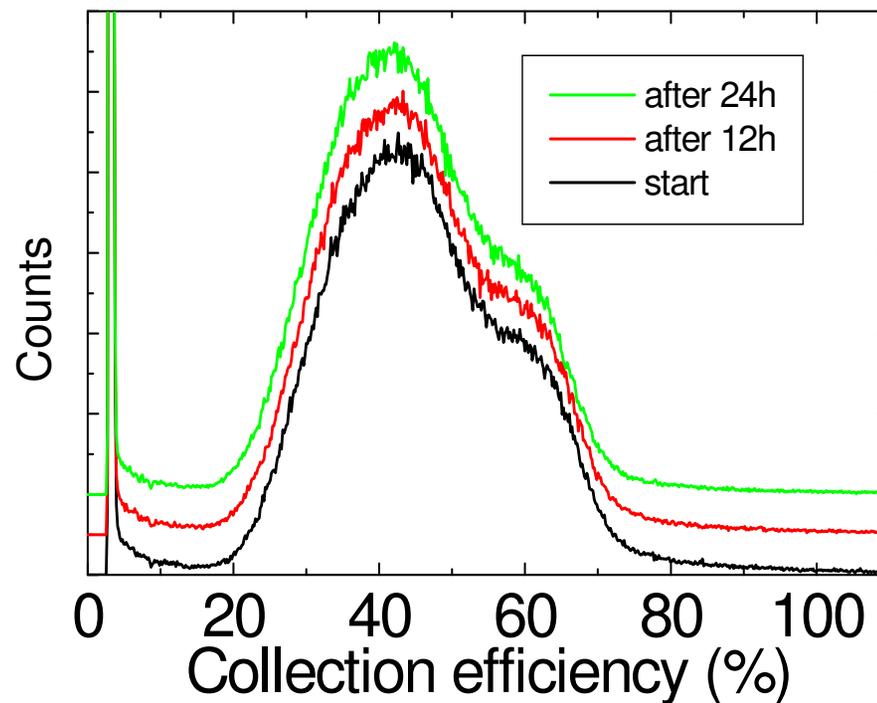
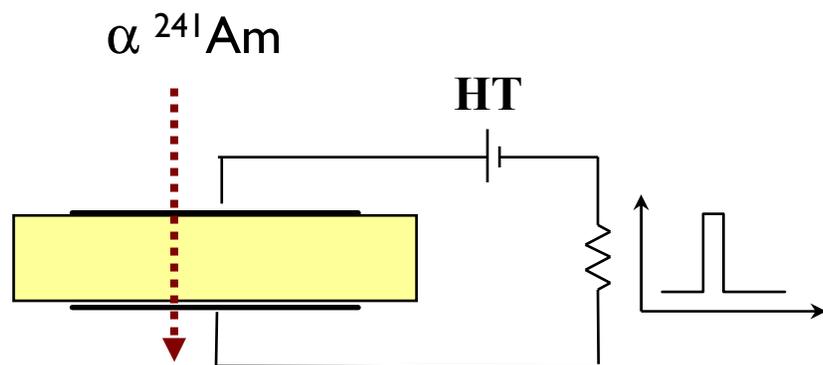
- ◆ *In-core nuclear reactors (EDF) :*  
 $\alpha$ , n, and intense  $\gamma$  fluxes monitoring
- ◆ *Nuclear waste processing (COGEMA):*  
corrosion hard  $\alpha$  counters
- ◆ *Synchrotrons (ESRF):*  
High transparency to low energy X rays  
Heat and flux resilient
- ◆ *Medical dosimetry :*  
tissue equivalence
- ◆ *Fast pulse metrology (defence)*  
lasers (UV, VUV), synchrotrons, X-ray flash pulses



# Alpha particle detection

Device optimisation :

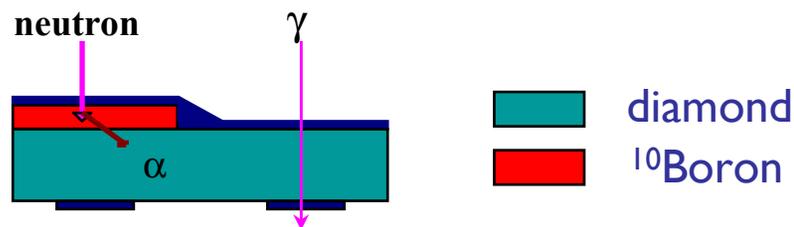
- stable  $\alpha$  detection  
(no polarisation)
- thin (20 to 30  $\mu\text{m}$ ) is best
- pumped (typ. 10Gy)



Aiming at probing neutron fluences in core of nuclear reactors :

Pros : naturally exhibiting high neutron to gamma selectivity + radiation hard

Neutrons are probed via  $\alpha$  detection

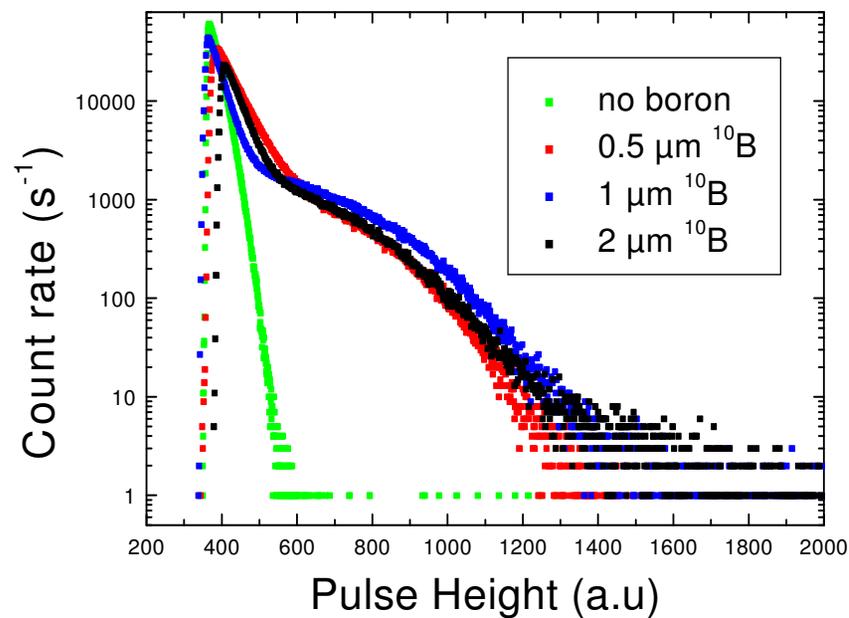


The neutron flux appears :

- as a 'continuum'

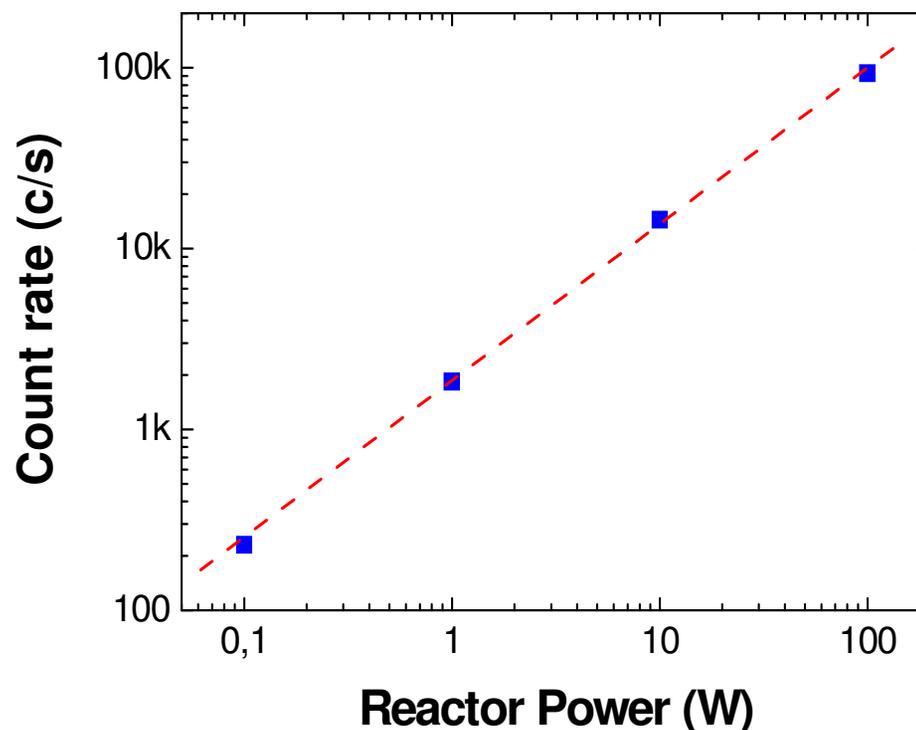
(angular distribution of the energy)

- the integral of the area above the no-boron  
gives the neutron counts  
(with high neutron to  $\gamma$  selectivity)



Mapping the neutron flux profile (Ulysse facility -exp. nuclear reactor, Saclay)

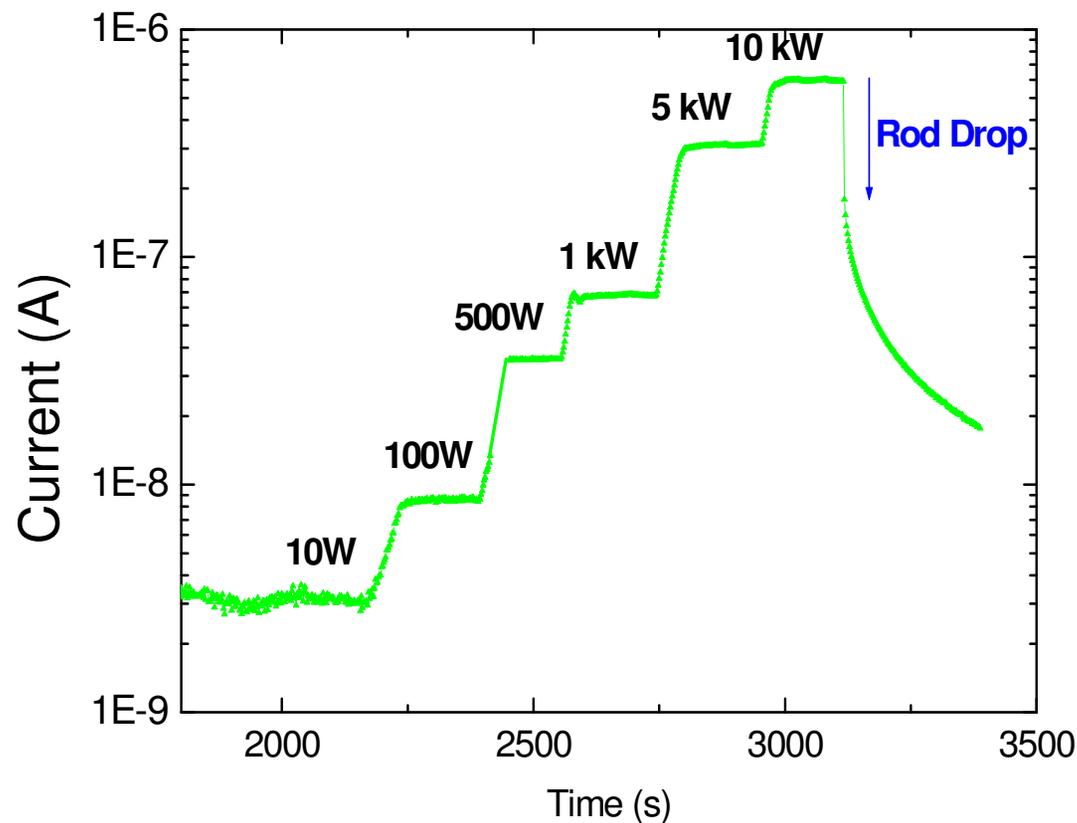
- Here device in-core (few 10 cm) :
- Linearity with the flux
- The overall efficiency is low (typ. 3% due to  $^{10}\text{B}$  conversion)
- Higher efficiencies have been obtained using  $^{235}\text{U}$  converter but... Uranium ... turns into Plutonium...



At higher neutron energies, the fluence can be measured from the induced current caused by the carbon recoil

No conversion layer needed

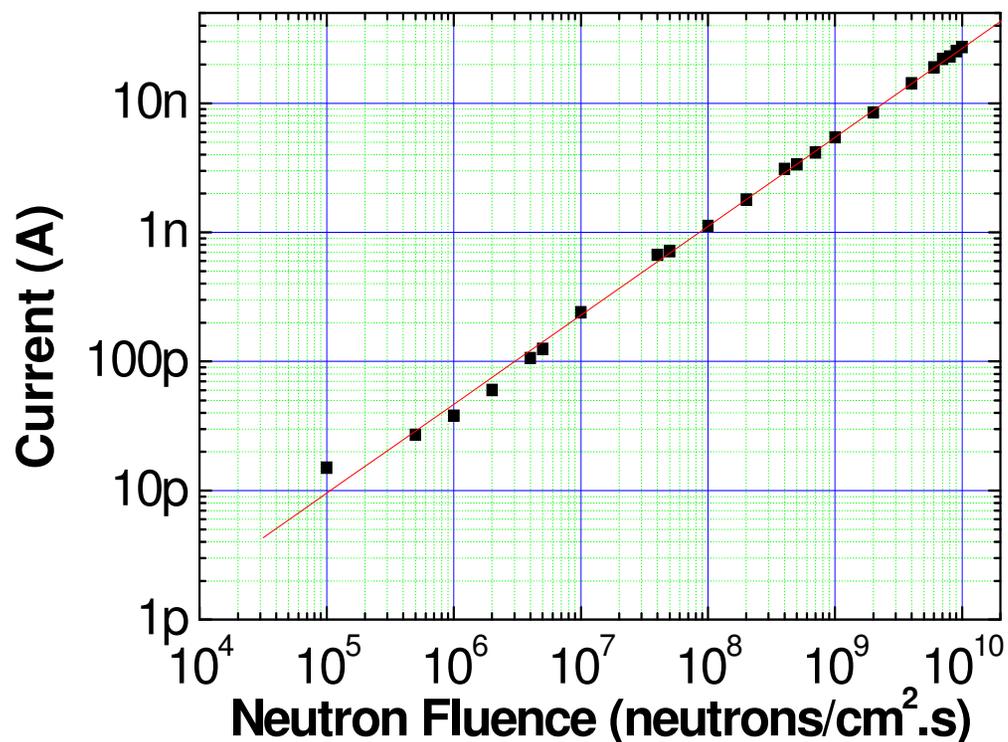
- Each  $^{12}\text{C}$  atoms 'receives'  $1/12^{\text{th}}$  of the neutron energy
- Only possible at high flux and neutron energies (fission neutrons)



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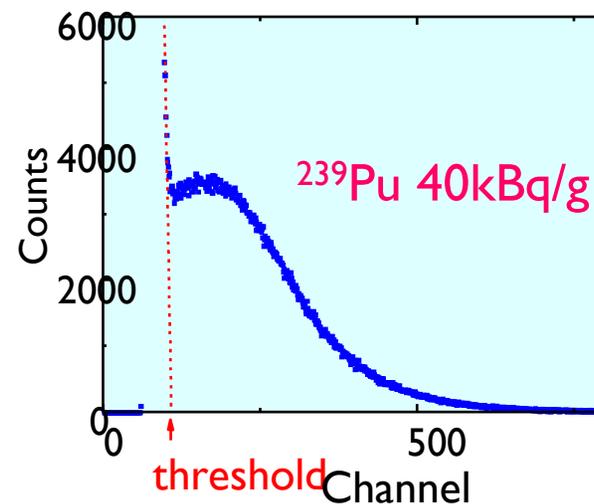




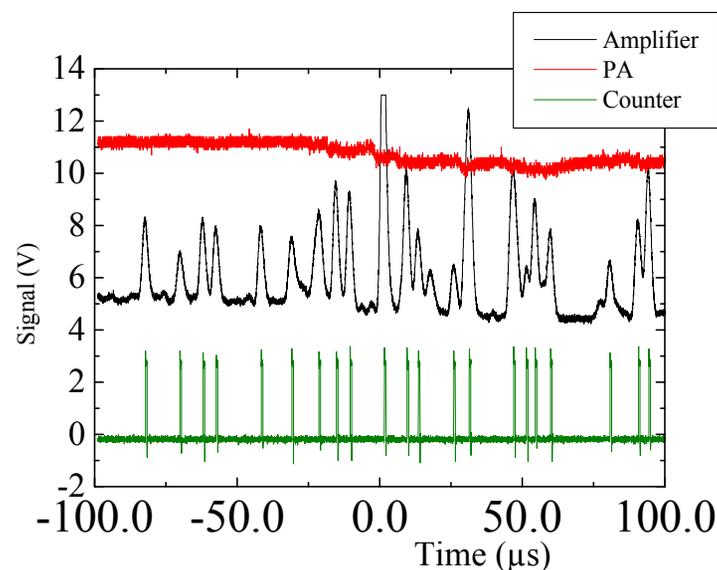
# Nuclear Detection Applications : Nuclear wastes

$\alpha$  detection in corrosive liquid sources  
Nuclear reprocessing plants (France + Japan)  
Devices used in Rokkasho-Mura plant

No alternative from CVD :  
Requires large area and thin material



**A**  
COGEMA



70.000 cts/s ; 2h  $\Leftrightarrow$  1 week real conditions

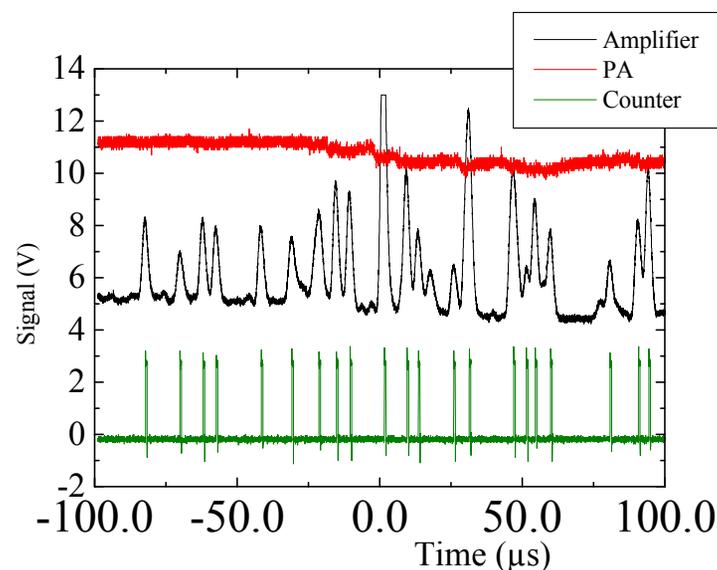
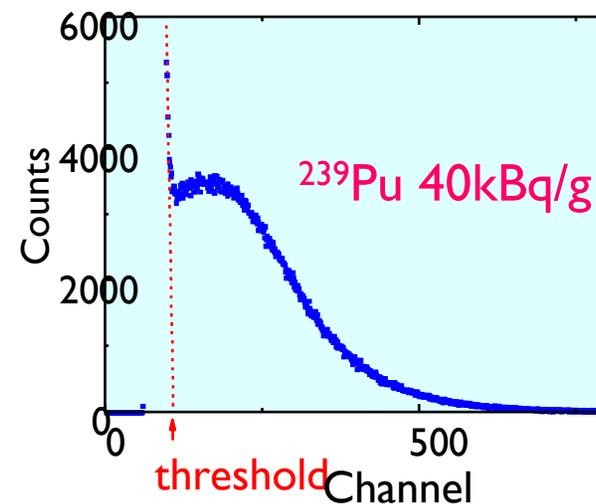
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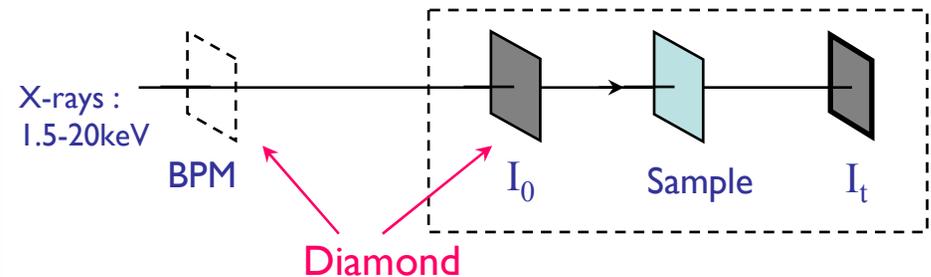
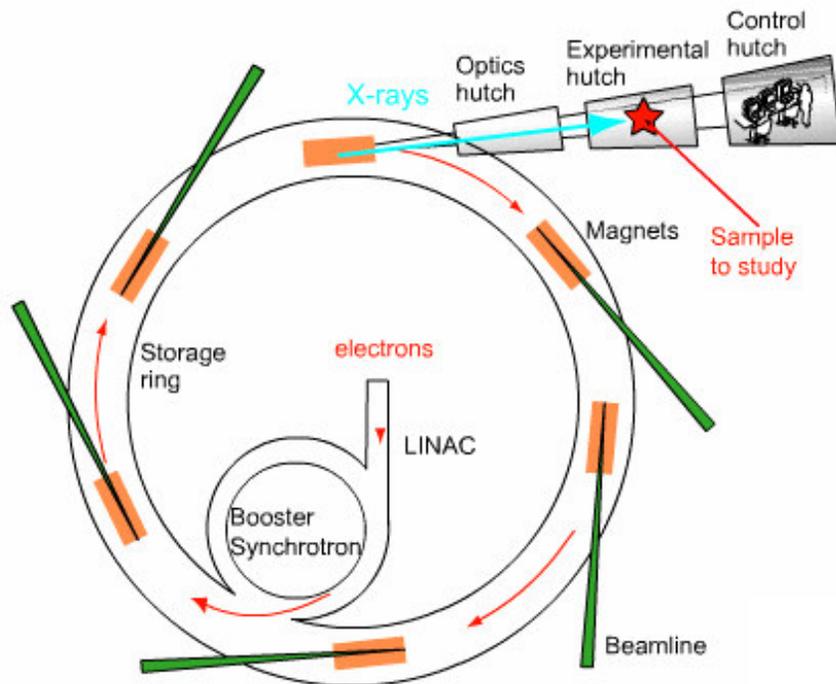
COGEMA



70.000 cts/s ; 2h  $\Leftrightarrow$  1 week real conditions

Aiming at probing the beam characteristics (position, intensity, profile) at low energies and with a semitransparent material

- in front end (white light, high fluences –  $10^{17}$  ph./s)
- in beam lines (monochromatic light,  $10^8$  –  $10^{13}$  ph/s)

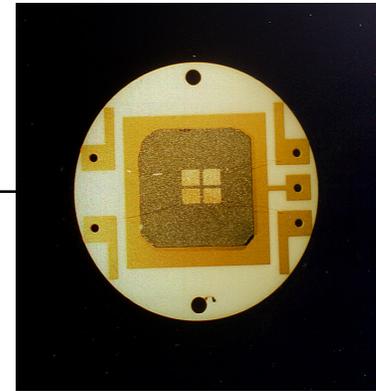


Monitoring devices must exhibit :

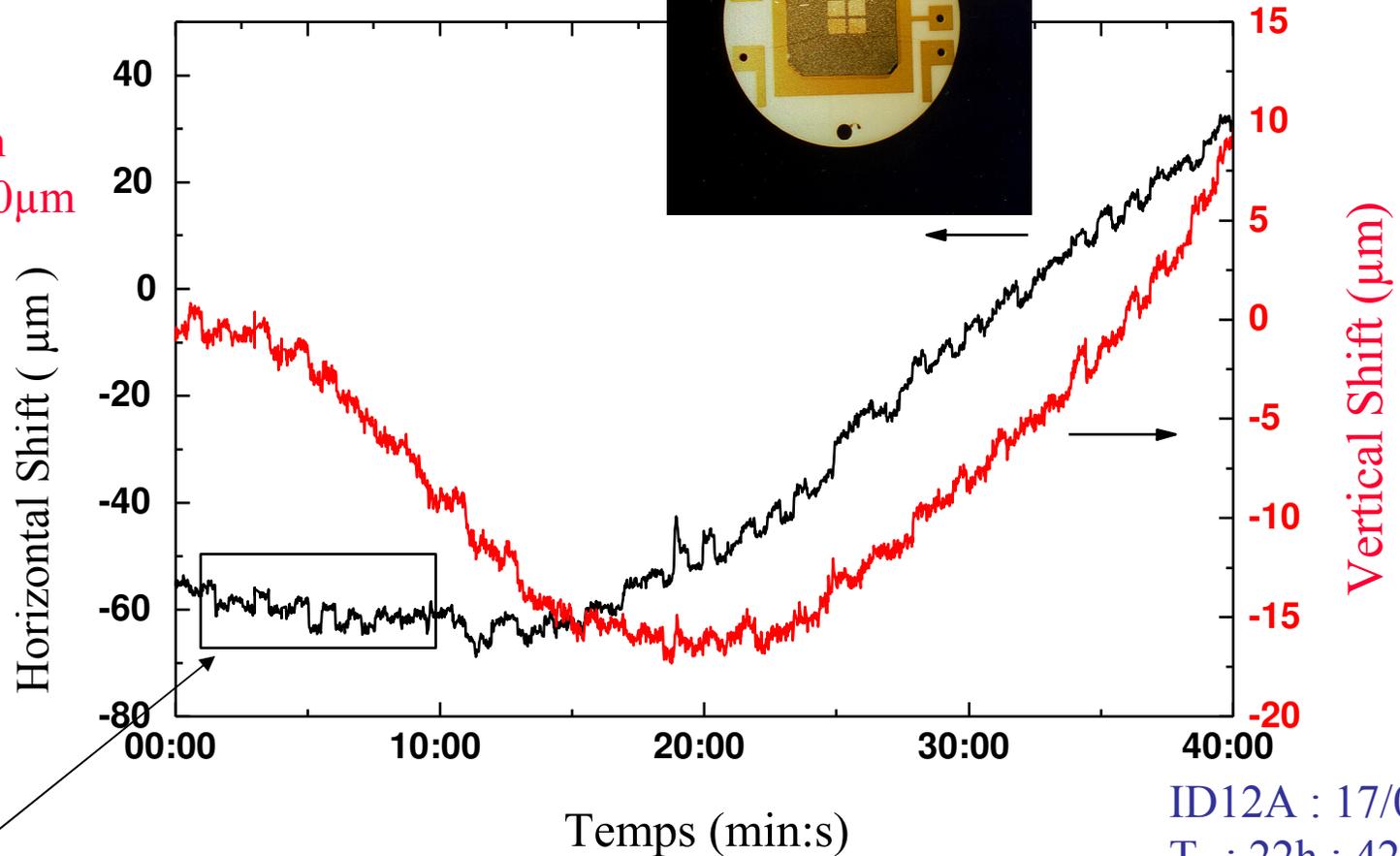
- high transparency (low Z)
  - fluence hardness
  - temperature hardness
  - mechanically resilient,
- Realisations have included
- Intensity monitors
  - Beam position monitors (2  $\mu\text{m}$  resol.)
  - Beam Profile monitors

# Probing the beam instabilities

## 4 quadrant semitransparent BPM



- Square beam
- $200\mu\text{m} \times 200\mu\text{m}$
- 4 keV



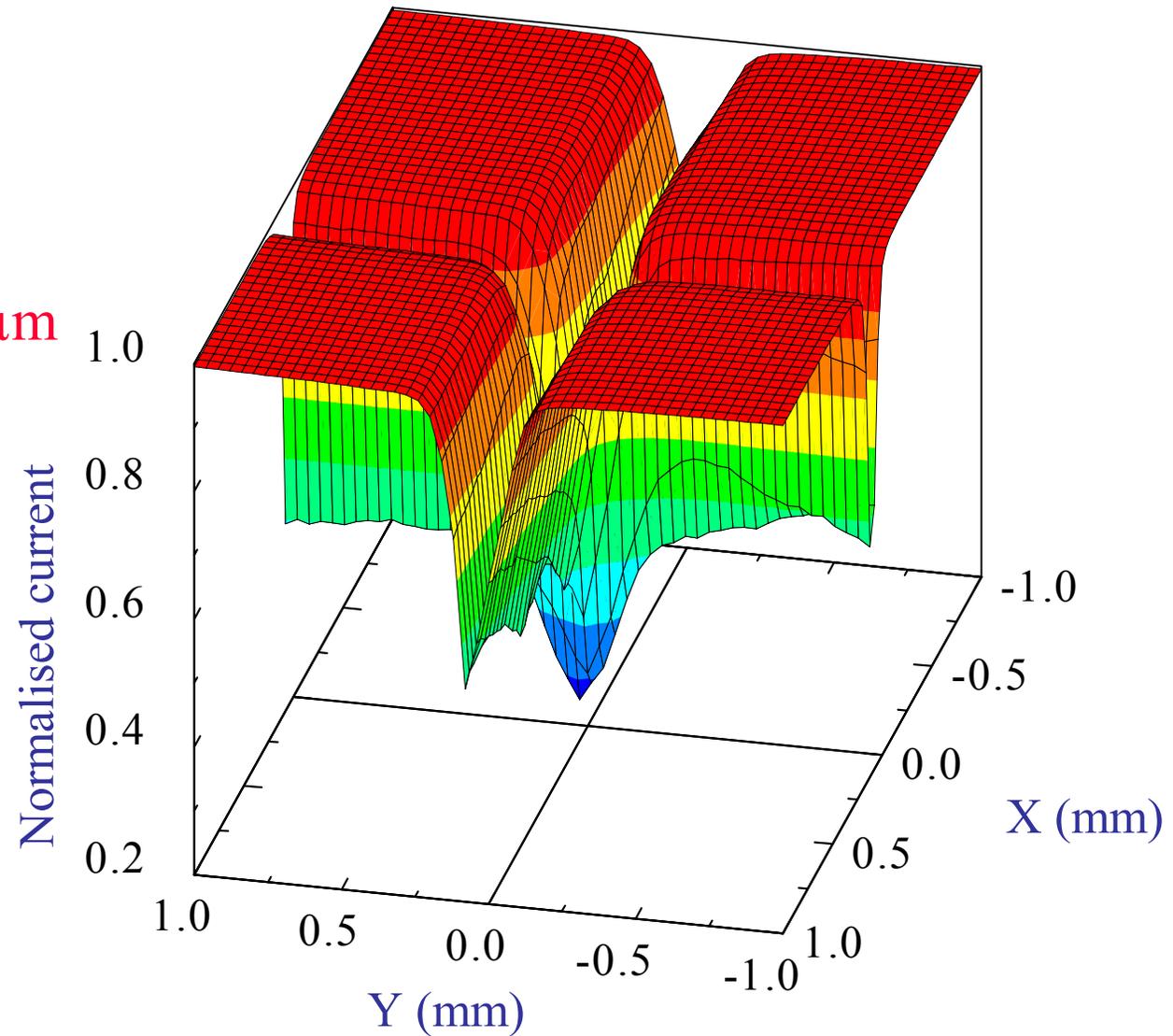
Beam global feedback  
causes the observed instabilities

Resolution well beyond  $2\mu\text{m}$



## Measured 3D scan response

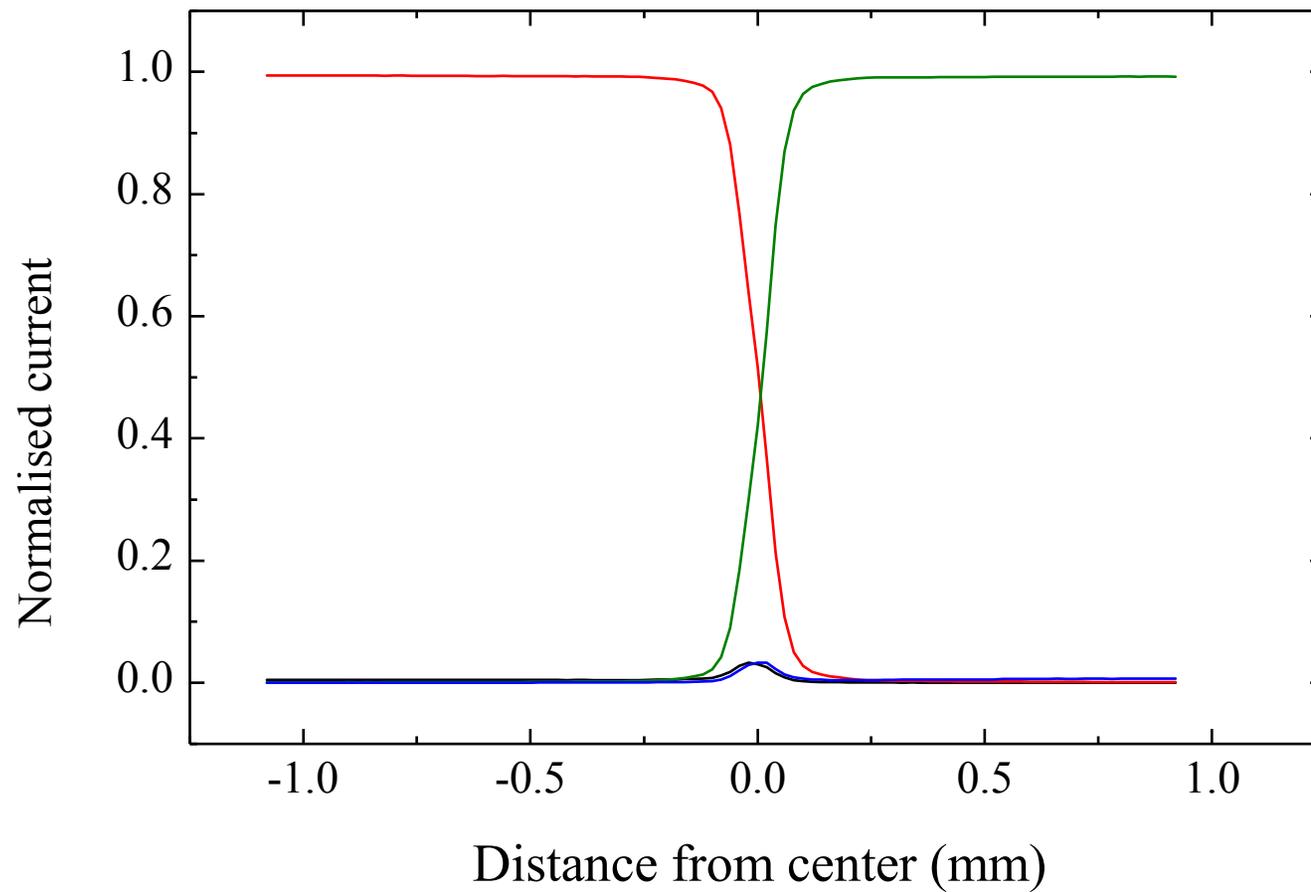
- square beam
- $200\mu\text{m} \times 200\mu\text{m}$
- 4 keV X-ray



scan direction

A   B  
D   C

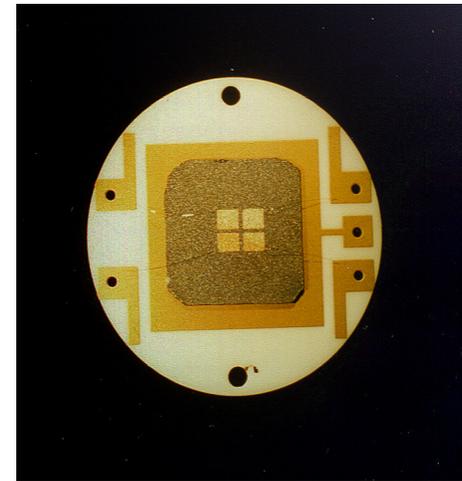
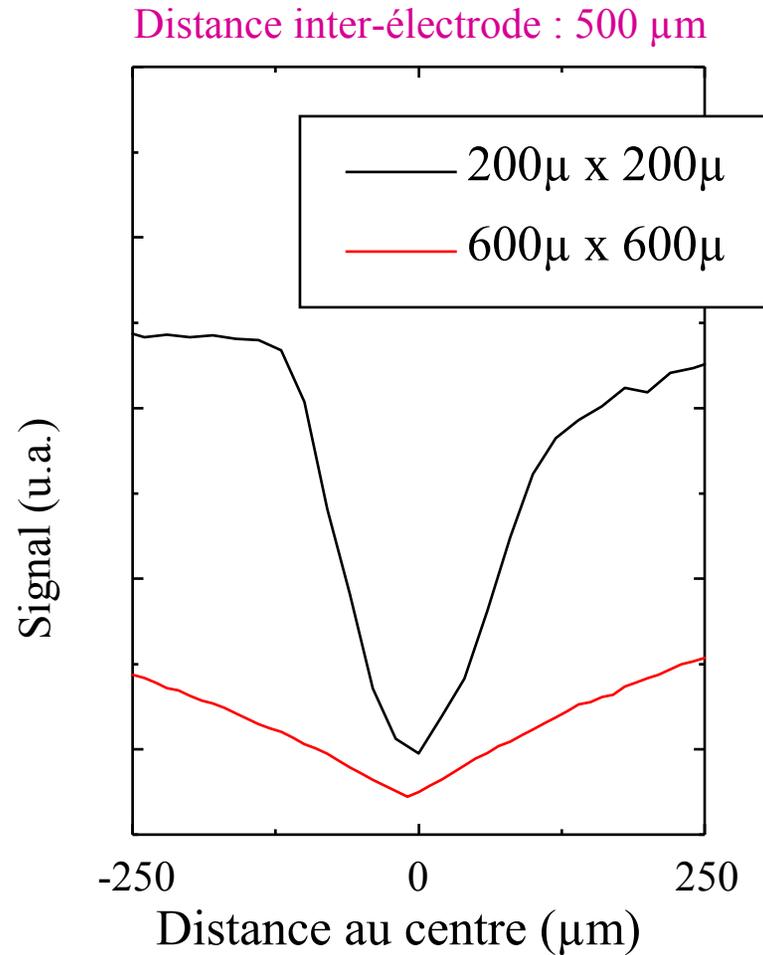
- square beam  
- 200 $\mu\text{m}$  x 200 $\mu\text{m}$   
- 4 keV X-ray





## Dispositif 4 quadrants :

Position du faisceau X : résolution  $< 2 \mu\text{m}$  , semi transparence



$\Rightarrow$  **Mais** la résolution dépend de la taille du faisceau

$\Rightarrow$  nouveau concept : dispositif résistif

# Capteurs à couche résistive:

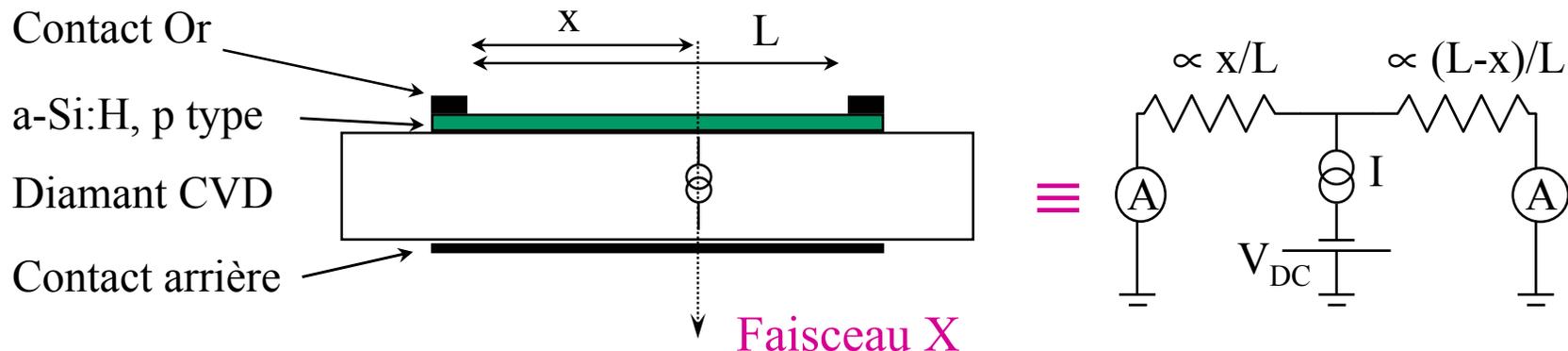
Principe :

une couche résistive d'épaisseur et de résistivité ajustée est déposée sur le diamant

⇒ division des courants entre les quatre contacts

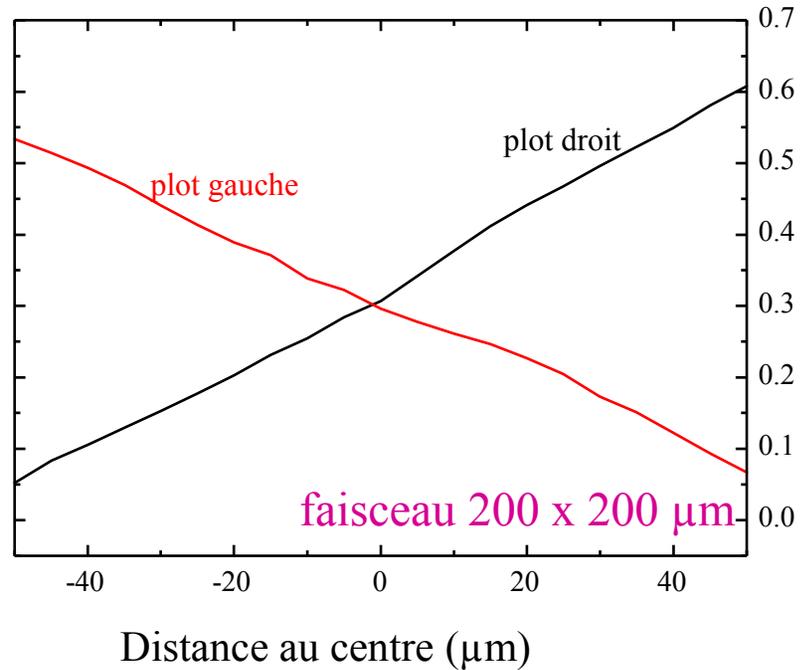
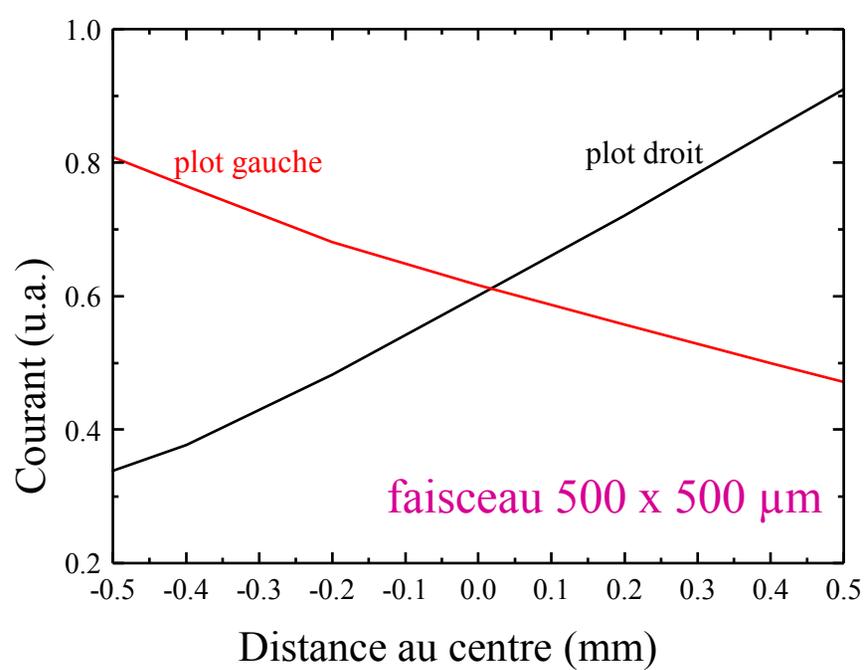
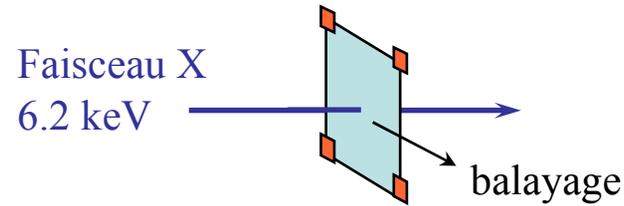
⇒ Le courant total reste constant

couche de a-Si:H , type p,  $\rho \approx 10^5 \Omega.cm$



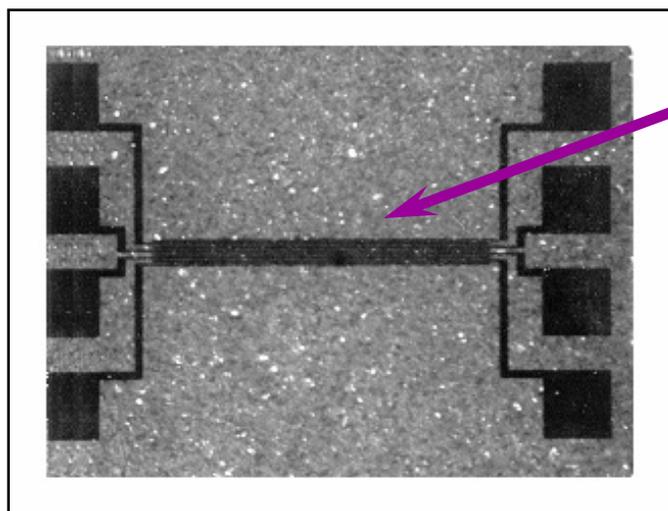


# Capteur à couche résistive : parfaite linéarité du détecteur

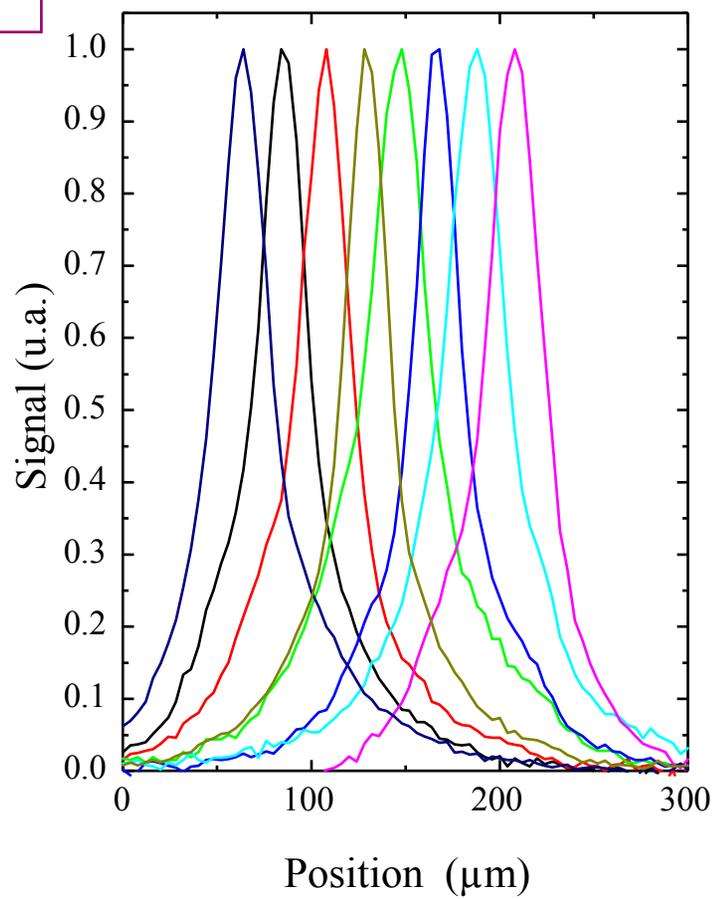
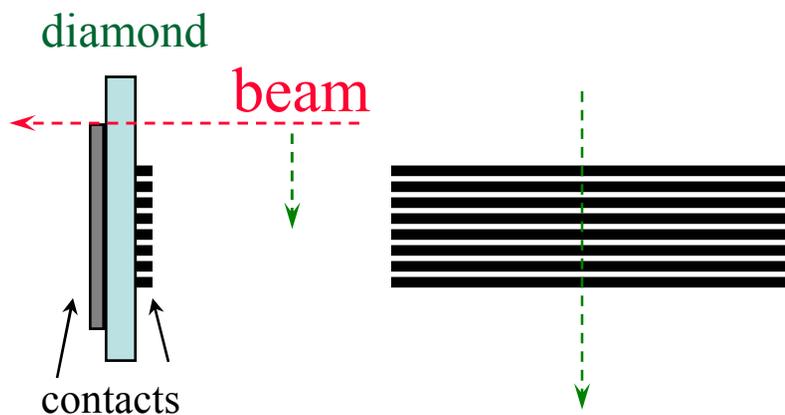


# Beam Profile Monitors

May efficiently be coupled with BPM



8 lines,  
width : 15 $\mu\text{m}$   
pitch : 20  $\mu\text{m}$

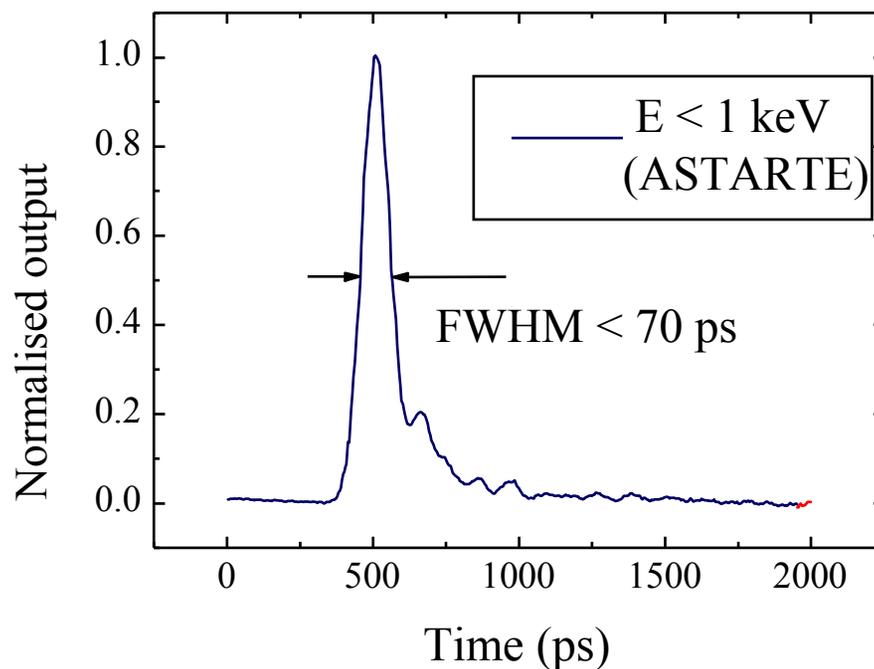


**Diamant = matériau rapide pour détection d'impulsions**

- 😊 : ♦ Faible durée de vie des porteurs
- ♦ Forte mobilité des porteurs
- ☹ : ♦ Faible sensibilité



**< 70 ps**



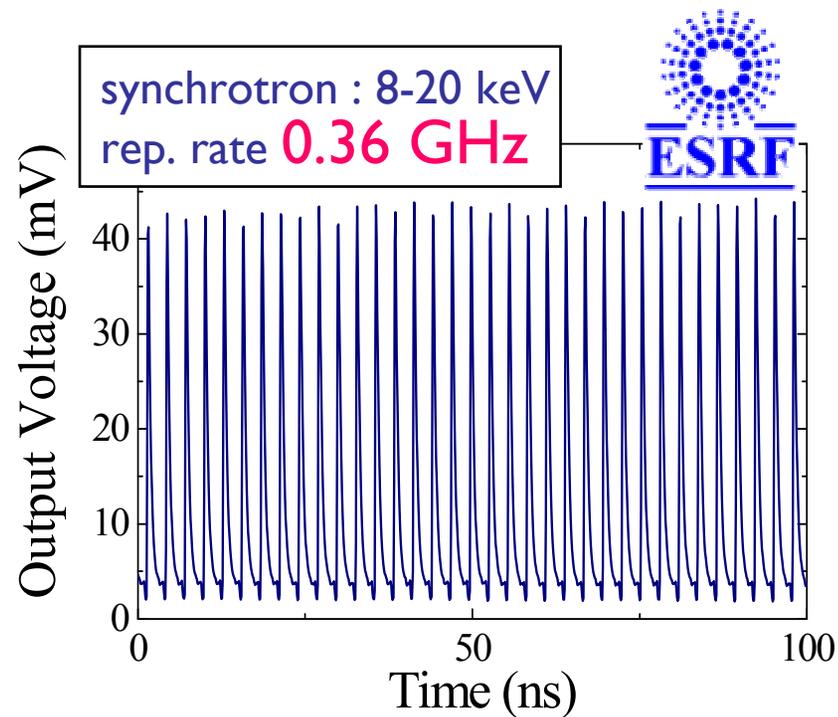
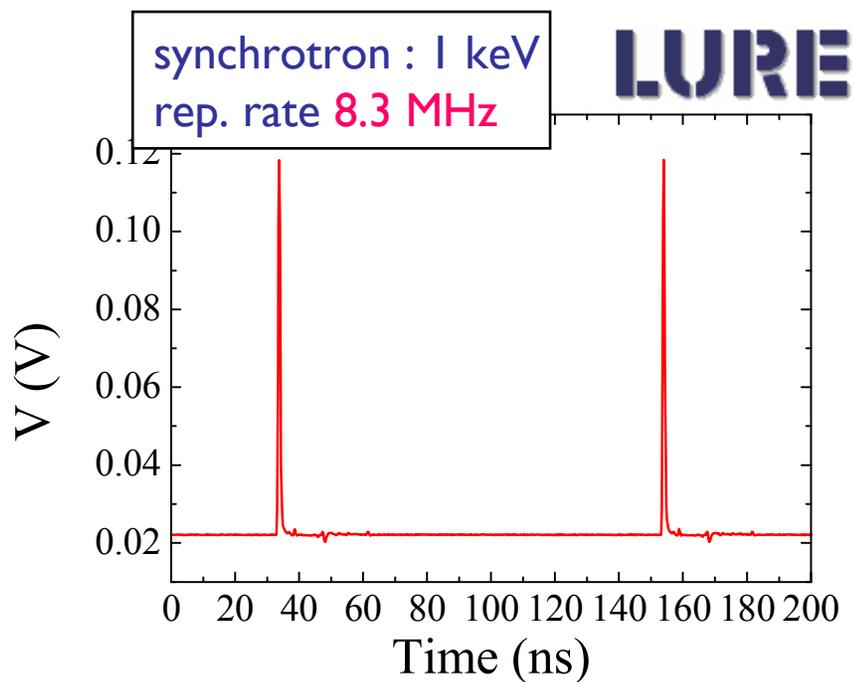
**Intérêts : mesure distribution temporelle faisceau synchrotron (ESRF)**

**Seule électronique : un détecteur + 1 oscillo**

# Ultra-fast pulse metrology

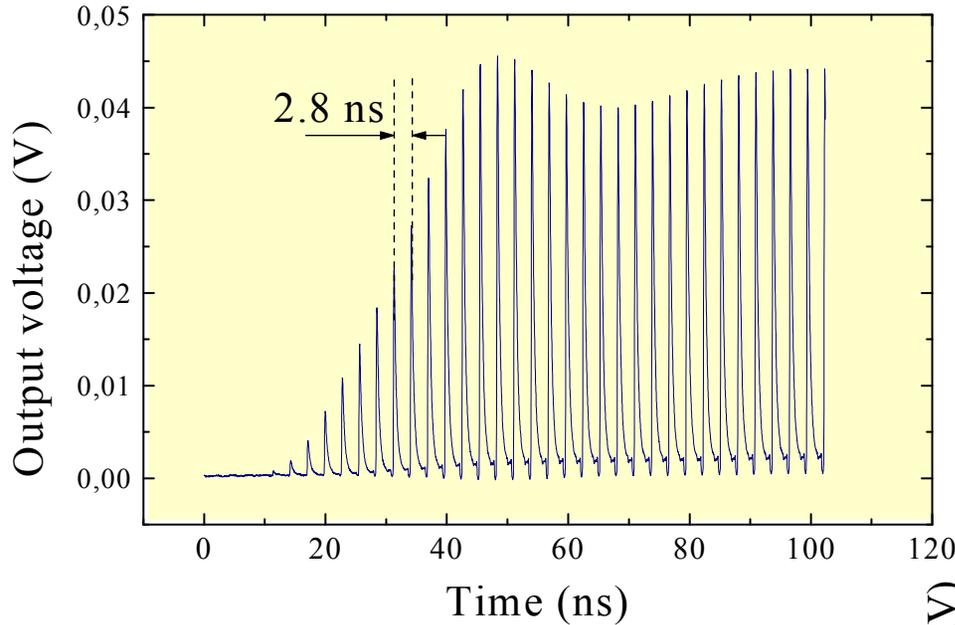
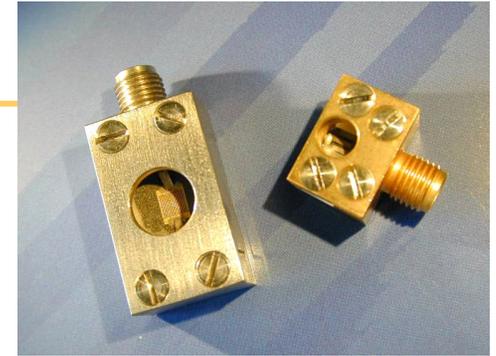


Application to synchrotron machine diagnostics  
(e.g., LURE, ESRF)





# Bunch temporal distribution

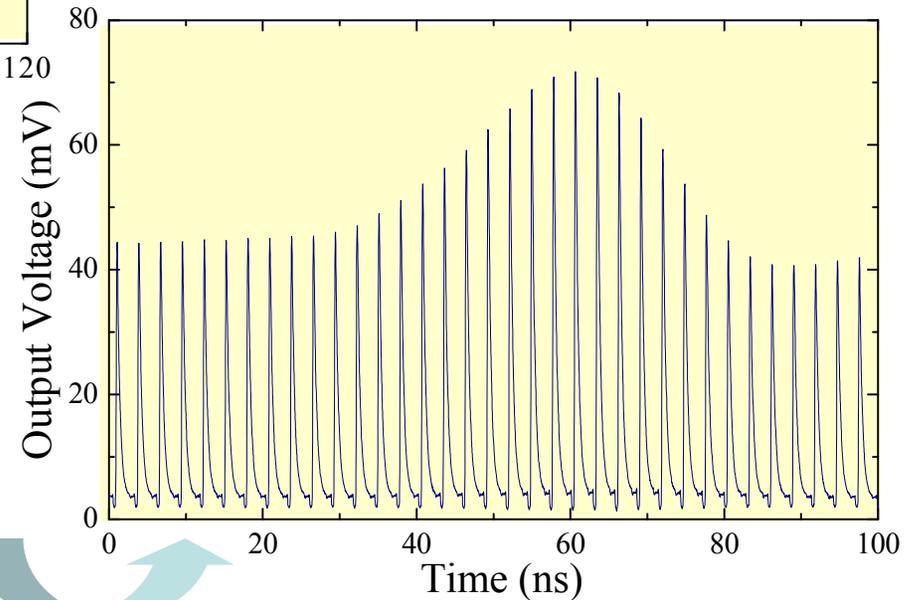
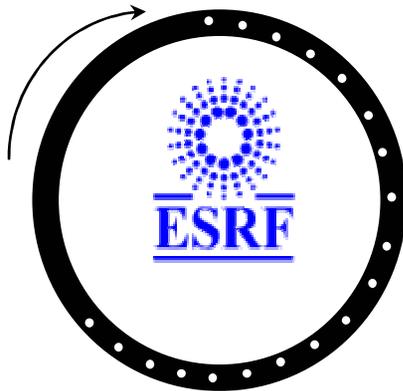


**ESRF (2/3<sup>rd</sup> filling)**

**BM5**

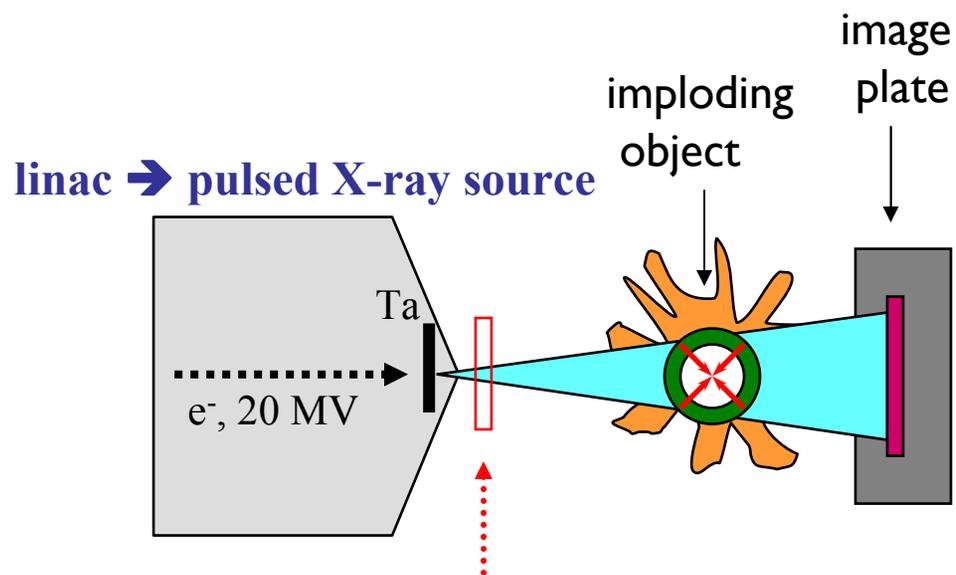
**White light**

**Device Temperature > 170°C**



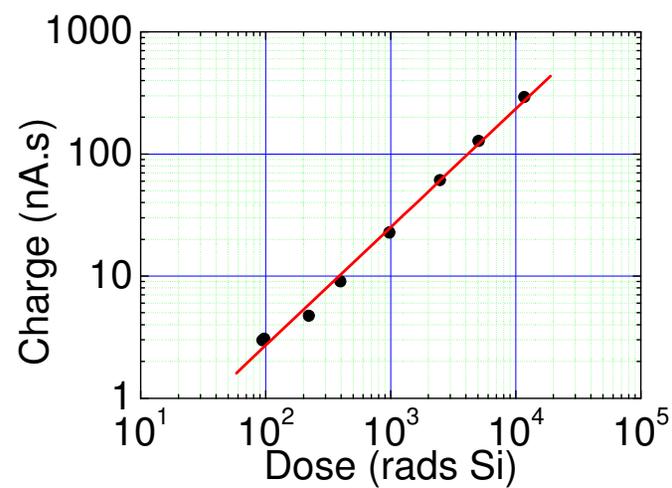
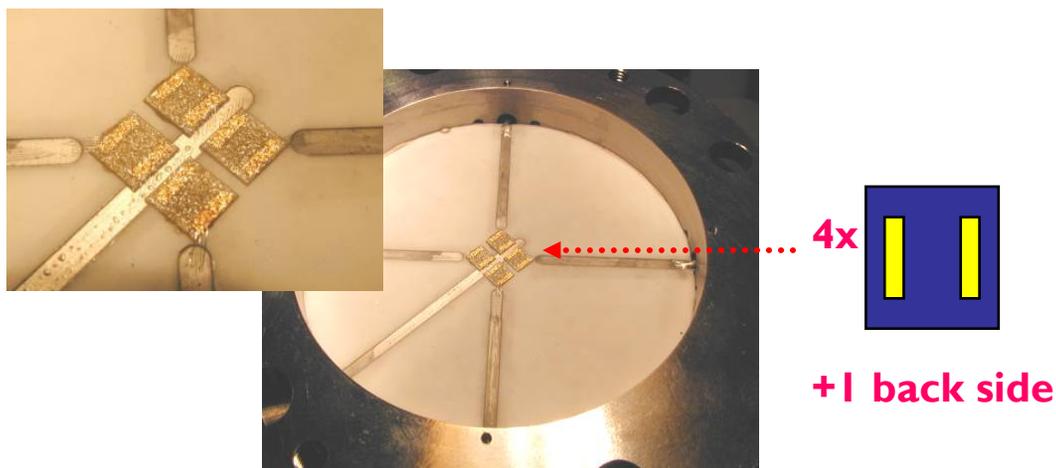
# Flash X-Ray radiography diagnosis tool (defence)

## AIRIX (Accélérateur à Induction de Radiographie pour l'Imagerie X)



### Demanding specifications

- ◆ typ.  $\approx 1 \text{ MeV}$
- ◆ Dose ( $< 5 \text{ krad (Si)/flash}$ )
- ◆ Duration : typ.  $50 \text{ ns FWHM}$
- ◆ 500 shots / yr / 15 yrs ( $> 15 \text{ Mrad}$ )
- ◆ Resilient (EMC and schock 10g)
- ◆ High transmission ( $< 0.1 \text{ g/cm}^2 (\text{W})$ )



👉 Detectors :

- Controlling the electronic characteristics with respect to the growth conditions is necessary for radiation detector fabrication
- Pre-optimisation of the devices is necessary (defects priming etc)

👉 Devices :

- for neutron detection in the core of nuclear reactors
- for alpha activity monitoring in acids
- ultra-fast pulse monitoring

👉 BUT : to date diamond detection :  
mostly addressing small markets ...

**CEA/Saclay**

**D. Tromson, M-J. Guerrero, C. Mer, S. Delclos,  
E. Snidero\*, M. Pomorski\*, M. Rebisz\***

**ESRF (microprobe analysis)**

**J. Morse, R. Barrett, W. Ludwig**

**IFN**

**P. Olko, B. Marcewska**

**IMO-IMEC**

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**UCL London + WSI Munich**

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